

3-MODE 200mA LDO REGULATOR

NO.EA-083-120404

OUTLINE

The R1160x Series consist of CMOS-based voltage regulator ICs with high output voltage accuracy, low supply current, and low ON-resistance. Each of these voltage regulator ICs consists of a voltage reference unit, an error amplifier, resistors for setting Output Voltage, a current limit circuit, and a chip enable circuit.

These ICs perform with low dropout voltage and a chip enable function. To prevent the destruction by over current, current limit circuit is included. The R1160x Series have 3-mode. One is standby mode with CE or standby control pin. Other two modes are realized with ECO pin™. Fast Transient Mode (FT mode) and Low Power Mode (LP mode) are alternative with ECO pin™. Consumption current is reduced to 1/10 at Low Power Mode compared with Fast Transient Mode. Output voltage is maintained between FT mode and LP mode.

The output voltage of these ICs is internally fixed with high accuracy. Since the packages for these ICs are SOT-23-5 and SON-6 (**Limited**) packages, high density mounting of the ICs on boards is possible.

FEATURES

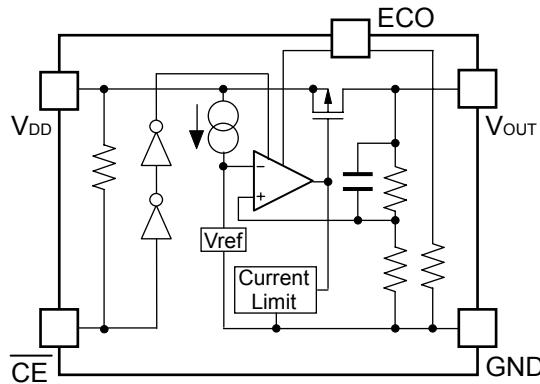
- Supply Current (Low Power Mode)..... Typ. $3.5\mu A$ ($V_{OUT} \leq 1.5V$)
- Supply Current (Fast Transient Mode)..... Typ. $40\mu A$
- Supply Current (Standby Mode)..... Typ. $0.1\mu A$
- Dropout Voltage Typ. $0.14V$ ($I_{OUT}=200mA, V_{OUT}=2.8V$)
- Ripple Rejection Typ. $70dB$ ($f=1kHz$, FT Mode)
- Temperature-Drift Coefficient of Output Voltage Typ. $\pm 100ppm/\text{ }^{\circ}\text{C}$
- Line Regulation Typ. $0.05\%/\text{V}$
- Output Voltage Accuracy $\pm 2.0\%$ ($\pm 3.0\%$ at LP Mode)
- Output Voltage Range 0.8V to 3.3V (0.1V steps)
(For other voltages, please refer to MARK INFORMATIONS.)
- Input Voltage Range 1.4V to 6.0V
- Built-in Fold Back Protection Circuit Typ. 50mA (Current at short mode)
- Packages SOT-23-5, SON-6 (**Limited**)

APPLICATIONS

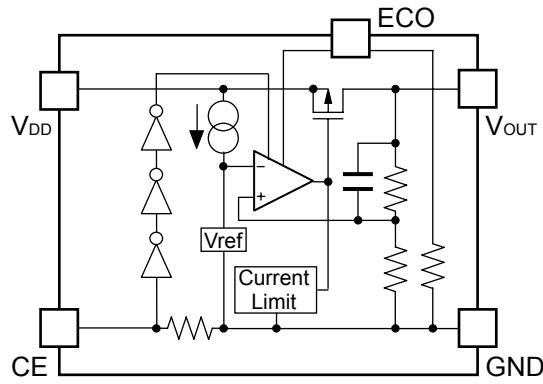
- Precision Voltage References.
- Power source for electrical appliances such as cameras, VCRs and hand-held communication equipment.
- Power source for battery-powered equipment.

BLOCK DIAGRAMS

R1160xxx1A



R1160xxx1B



SELECTION GUIDE

The output voltage, chip enable polarity, and package, etc. for the ICs can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1160Nxx1*-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes
R1160Dxx1*-TR-FE	SON-6 (Limited)	3,000 pcs	Yes	Yes

xx: The output voltage can be designated in the range from 0.8V(08) to 3.3V(33) in 0.1V steps.
 (For other voltages, please refer to MARK INFORMATIONS.)

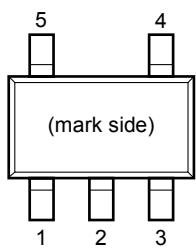
* : CE pin polarity are options as follows.
 (A) "L" active type.
 (B) "H" active type.

The products scheduled to be discontinued (be sold to limited customer) : "Limited"

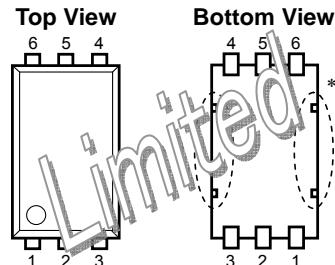
These products will be discontinued in the future. You can not select these products newly.
 We will provide these products to the customer who has been using or has ordered them before.
 But we recommend changing to other products as soon as possible.

PIN CONFIGURATION

- SOT-23-5



- SON-6



PIN DESCRIPTIONS

- SOT-23-5

Pin No	Symbol	Pin Description
1	V _{DD}	Input Pin
2	GND	Ground Pin
3	\overline{CE} or CE	Chip Enable Pin
4	ECO	MODE alternative pin
5	V _{OUT}	Output Pin

- SON-6 (Limited)

Pin No	Symbol	Pin Description
1	V _{DD}	Input Pin
2	NC	No Connection
3	V _{OUT}	Output Pin
4	ECO	MODE alternative pin
5	GND	Ground Pin
6	\overline{CE} or CE	Chip Enable Pin

*) Tab suspension leads are GND level. (They are connected to the reverse side of this IC.)

The tab suspension leads should be open and do not connect to other wires or land patterns.

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	6.5	V
V_{ECO}	Input Voltage (ECO Pin)	-0.3 to $V_{IN}+0.3$	V
V_{CE}	Input Voltage (\overline{CE} or CE Pin)	-0.3 to $V_{IN}+0.3$	V
V_{OUT}	Output Voltage	-0.3 to $V_{IN}+0.3$	V
I_{OUT}	Output Current	250	mA
P_D	Power Dissipation (SOT-23-5)*	420	mW
	Power Dissipation (SON-6) (Limited)*	500	mW
T_{opt}	Operating Temperature Range	-40 to 85	°C
T_{stg}	Storage Temperature Range	-55 to 125	°C

*) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

• R1160xxx1A

Topt=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V _{OUT}	Output Voltage (FT Mode)	V _{IN} =Set V _{OUT} +1V, V _{ECO} =V _{IN} 1μA ≤ I _{OUT} ≤ 30mA *1	×0.98 (-30mV)		×1.02 (30mV)	V
	Output Voltage (LP Mode)	V _{IN} =Set V _{OUT} +1V, V _{ECO} =GND 1μA ≤ I _{OUT} ≤ 30mA *2	×0.97 (-45mV)		×1.03 (45mV)	V
I _{OUT}	Output Current	V _{IN} -V _{OUT} =1V	200			mA
ΔV _{OUT} /ΔI _{OUT}	Load Regulation (FT Mode)	V _{IN} =Set V _{OUT} +1V, V _{ECO} =V _{IN} 1mA ≤ I _{OUT} ≤ 200mA		20	40	mV
	Load Regulation (LP Mode)	V _{IN} =Set V _{OUT} +1V, V _{ECO} =GND 1mA ≤ I _{OUT} ≤ 100mA		10	40	mV
V _{DIF}	Dropout Voltage	Refer to the ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE				
I _{SS1}	Supply Current (FT Mode)	V _{IN} =Set V _{OUT} +1V, V _{ECO} =V _{IN} ,		40	70	μA
I _{SS2}	Supply Current (LP Mode)	V _{IN} =Set V _{OUT} +1V, V _{OUT} ≤ 1.5V, V _{ECO} =GND		3.5	6.0	μA
		V _{IN} =Set V _{OUT} +1V, V _{OUT} ≥ 1.6V, V _{ECO} =GND		4.5	8.0	μA
I _{standby}	Supply Current (Standby)	V _{IN} =V _{CE} =Set V _{OUT} +1V V _{ECO} =GND or V _{IN}		0.1	1.0	μA
ΔV _{OUT} /ΔV _{IN}	Line Regulation (FT Mode)	Set V _{OUT} +0.5V ≤ V _{IN} ≤ 6V I _{OUT} =30mA, V _{ECO} =V _{IN} (In case that V _{OUT} ≤ 0.9V, 1.4V ≤ V _{IN} ≤ 6V)		0.05	0.20	%/V
	Line Regulation (LP Mode)	Set V _{OUT} +0.5V ≤ V _{IN} ≤ 6V I _{OUT} =30mA, V _{ECO} =GND (In case that V _{OUT} ≤ 0.9V, 1.4V ≤ V _{IN} ≤ 6V)		0.10	0.30	%/V
RR	Ripple Rejection (FT Mode)	f=1kHz, Ripple 0.2Vp-p V _{IN} =Set V _{OUT} +1V I _{OUT} =30mA, V _{ECO} =V _{IN}		70		dB
V _{IN}	Input Voltage		1.4		6.0	V
ΔV _{OUT} / ΔTopt	Output Voltage Temperature Coefficient	I _{OUT} =30mA -40°C ≤ Topt ≤ 85°C		±100		ppm /°C
I _{SC}	Short Current Limit	V _{OUT} =0V		50		mA
R _{PUC}	CE Pull-up Resistance		2.0	5.0	14.0	MΩ
R _{PDE}	ECO Pull-down Resistance		1.5	5.0	14.0	MΩ
V _{CEH}	CE ,ECO Input Voltage "H"		1.0		V _{IN}	V
V _{CEL}	CE ,ECO Input Voltage "L"		0		0.3	V

*1 : ±30mV Tolerance for V_{OUT} ≤ 1.5V*2 : ±45mV Tolerance for V_{OUT} ≤ 1.5V

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- R1160xxx1B

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V _{OUT}	Output Voltage (FT Mode)	V _{IN} =Set V _{OUT} +1V, V _{ECO} =V _{IN} 1μA ≤ I _{OUT} ≤ 30mA ^{*1}	x0.980 (-30mV)		x1.020 (30mV)	V
	Output Voltage (LP Mode)	V _{IN} =Set V _{OUT} +1V, V _{ECO} =GND 1μA ≤ I _{OUT} ≤ 30mA ^{*2}	x0.970 (-45mV)		x1.030 (45mV)	V
I _{OUT}	Output Current	V _{IN} -V _{OUT} =1V	200			mA
ΔV _{OUT} /ΔI _{OUT}	Load Regulation (FT Mode)	V _{IN} =Set V _{OUT} +1V, V _{ECO} =V _{IN} 1mA ≤ I _{OUT} ≤ 200mA		20	40	mV
	Load Regulation (LP Mode)	V _{IN} =Set V _{OUT} +1V, V _{ECO} =GND 1mA ≤ I _{OUT} ≤ 100mA		10	40	mV
V _{DIF}	Dropout Voltage	Refer to the ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE				
I _{SS1}	Supply Current (FT Mode)	V _{IN} =Set V _{OUT} +1V, V _{ECO} =V _{IN}		40	70	μA
I _{SS2}	Supply Current (LP Mode)	V _{IN} =Set V _{OUT} +1V, V _{OUT} ≤ 1.5V, V _{ECO} =GND		3.5	6.0	μA
		V _{IN} =Set V _{OUT} +1V, V _{OUT} ≥ 1.6V, V _{ECO} =GND		4.5	8.0	μA
I _{STANDBY}	Supply Current (Standby)	V _{IN} =Set V _{OUT} +1V V _{CE} =GND, V _{ECO} =GND or V _{IN}		0.1	1.0	μA
ΔV _{OUT} /ΔV _{IN}	Line Regulation (FT Mode)	Set V _{OUT} +0.5V ≤ V _{IN} ≤ 6.0V I _{OUT} =30mA, V _{ECO} =V _{IN} (In case that V _{OUT} ≤ 0.9V, 1.4V ≤ V _{IN} ≤ 6V)		0.05	0.20	%/V
	Line Regulation (LP Mode)	Set V _{OUT} +0.5V ≤ V _{IN} ≤ 6.0V I _{OUT} =30mA, V _{ECO} =GND (In case that V _{OUT} ≤ 0.9V, 1.4V ≤ V _{IN} ≤ 6V)		0.10	0.30	%/V
RR	Ripple Rejection (FT Mode)	f=1kHz, Ripple 0.2Vp-p V _{IN} =Set V _{OUT} +1V I _{OUT} =30mA, V _{ECO} =V _{IN}		70		dB
V _{IN}	Input Voltage		1.4		6.0	V
ΔV _{OUT} / ΔT _{OPT}	Output Voltage Temperature Coefficient	I _{OUT} =30mA -40°C ≤ T _{OPT} ≤ 85°C		±100		ppm /°C
I _{SC}	Short Current Limit	V _{OUT} =0V		50		mA
R _{PDC}	CE Pull-down Resistance		2.0	5.0	14.0	MΩ
R _{PDE}	ECO Pull-down Resistance		1.5	5.0	14.0	MΩ
V _{CEH}	CE, ECO Input Voltage "H"		1.0		V _{IN}	V
V _{CEL}	CE, ECO Input Voltage "L"		0		0.3	V

*1 : ±30mV Tolerance for V_{OUT} ≤ 1.5V

*2 : ±45mV Tolerance for V_{OUT} ≤ 1.5V

- ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE

Output Voltage V_{OUT} (V)	Dropout Voltage V_{DIF} (V)		
	Condition	Typ.	Max.
$0.8 \leq V_{OUT} \leq 0.9$	$I_{OUT}=200mA$	0.40	0.70
		0.30	0.50
		0.20	0.30
		0.14	0.20 (ECO="H") 0.25 (ECO="L")

TEST CIRCUITS

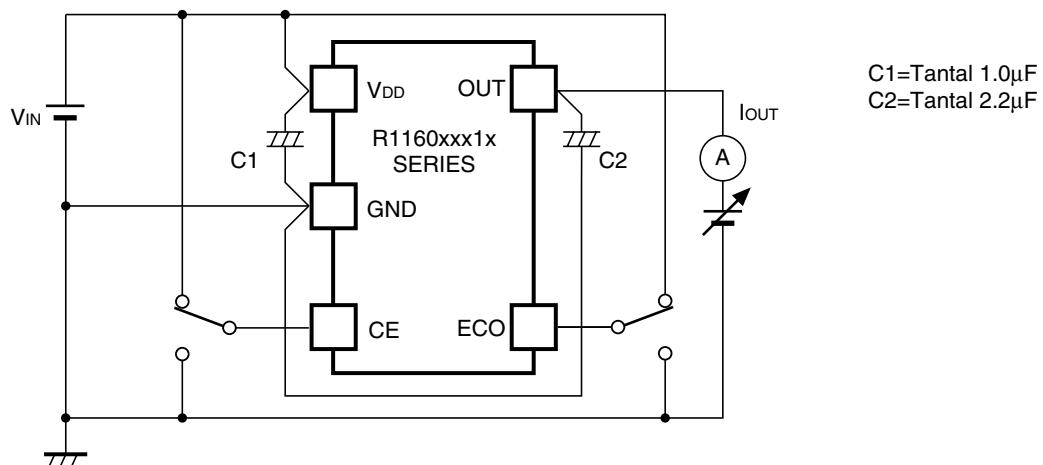


Fig.1 Output Voltage vs. Output Current Test Circuit

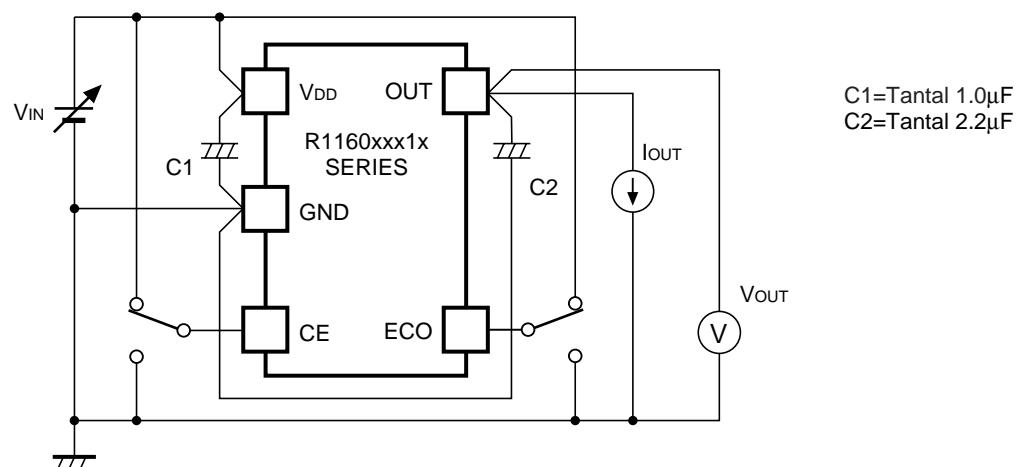


Fig.2 Output Voltage vs. Input Voltage Test Circuit

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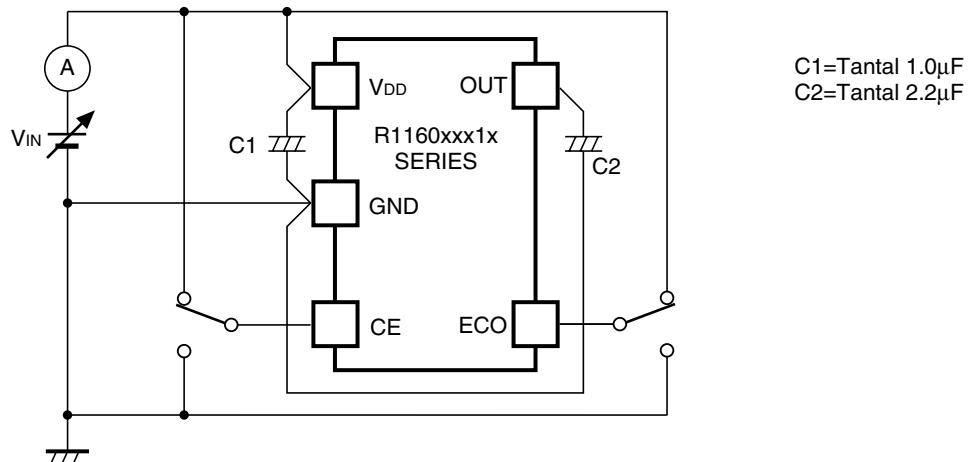


Fig.3 Supply Current vs. Input Voltage Test Circuit

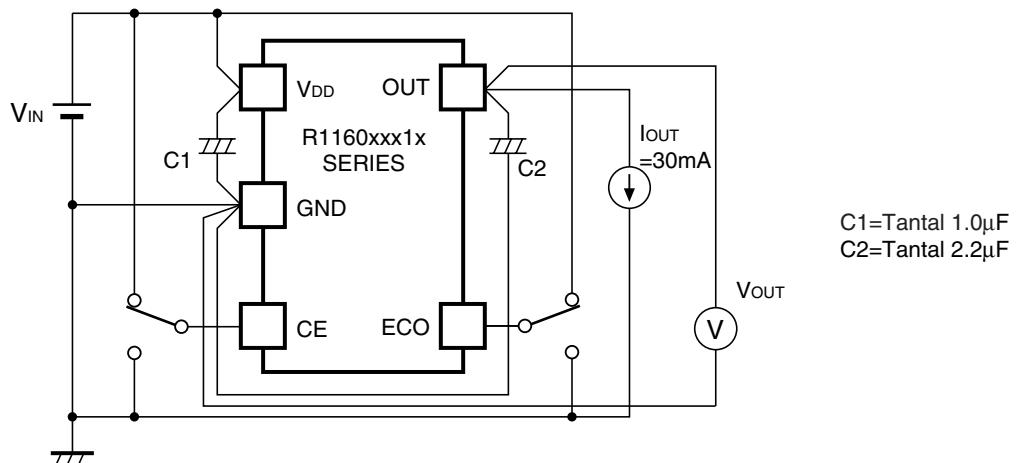


Fig.4 Output Voltage vs. Temperature Test Circuit

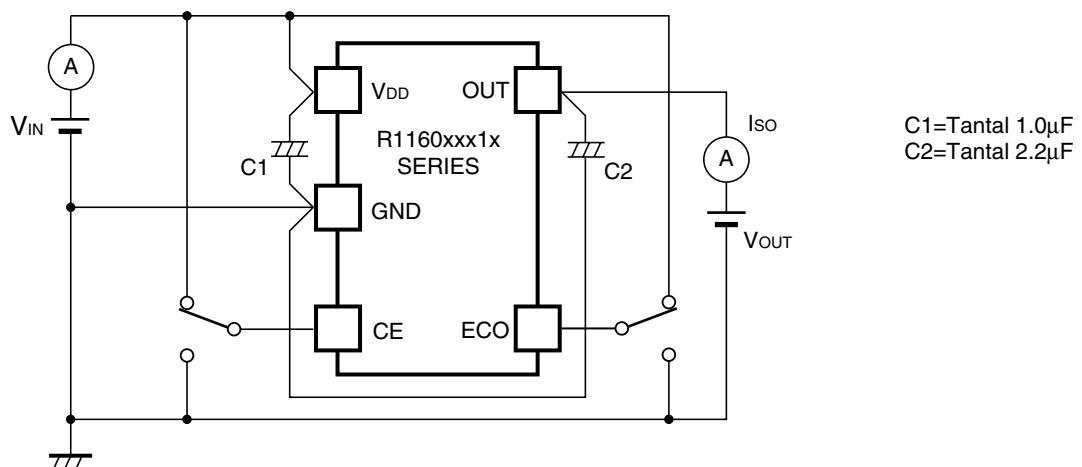


Fig.5 Supply Current vs. Temperature Test Circuit

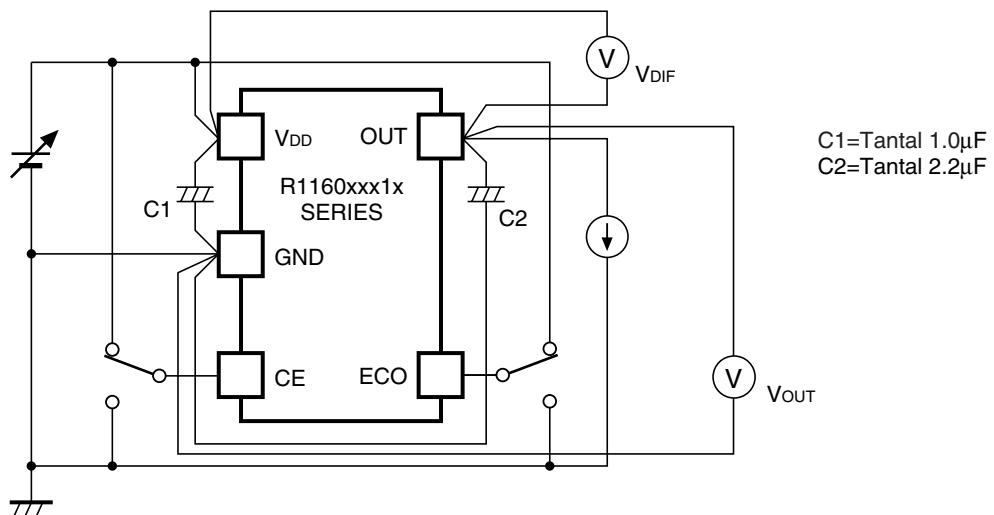


Fig. 6 Dropout Voltage vs. Output Current/ Set Output Voltage Test Circuit

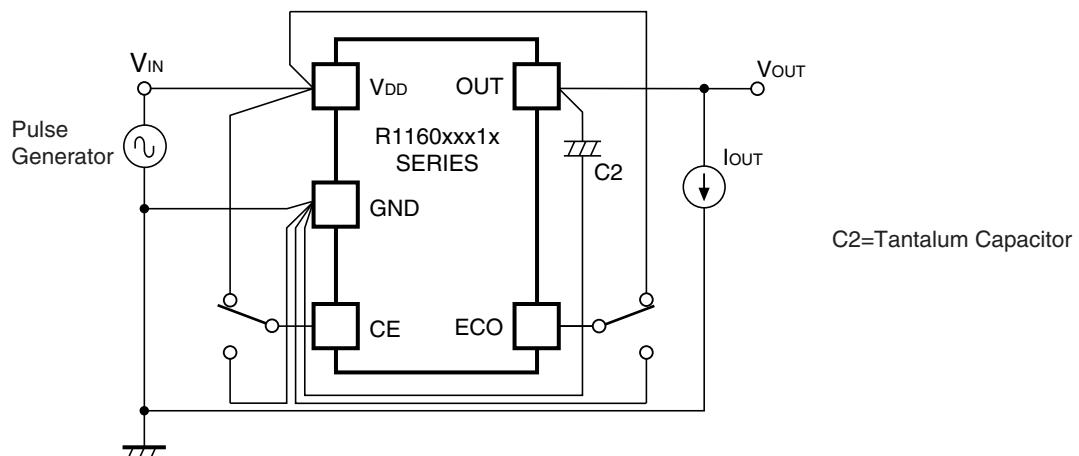


Fig. 7 Ripple Rejection Test Circuit

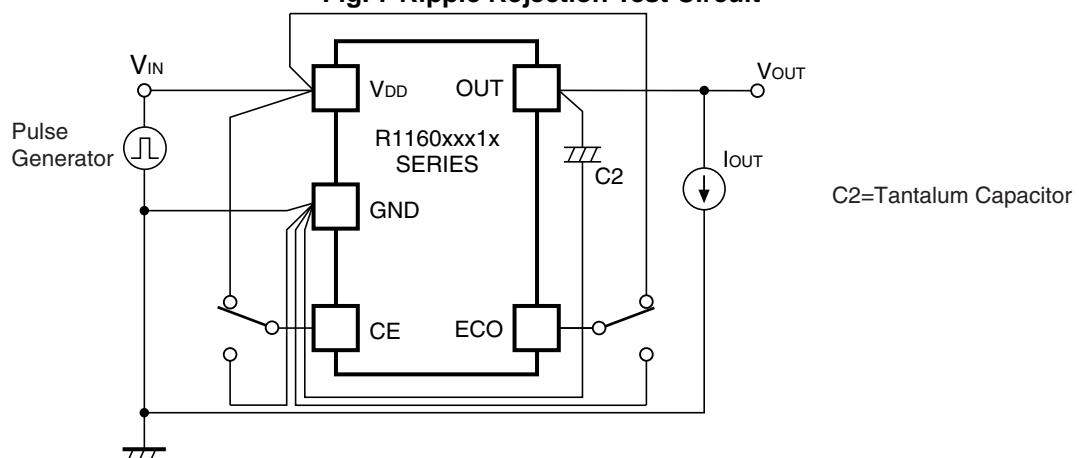


Fig.8 Input Transient Response Test Circuit

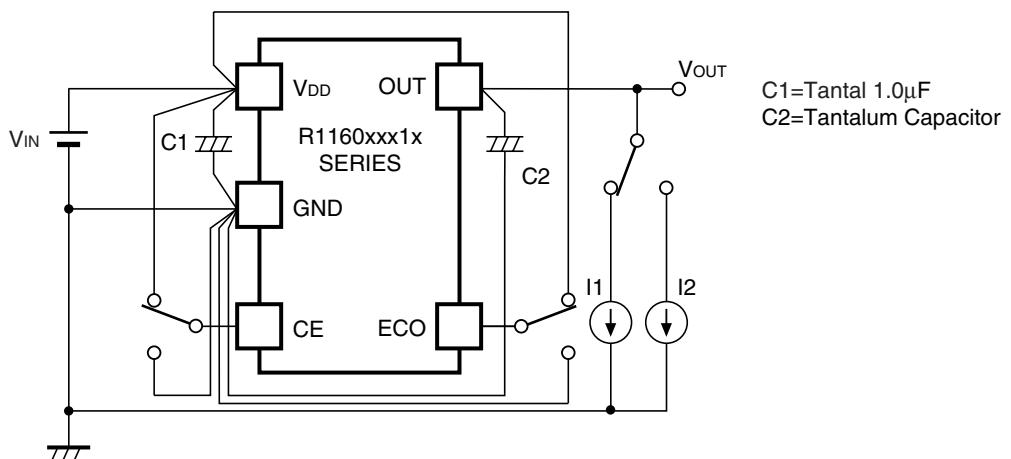


Fig.9 Load Transient Response Test Circuit

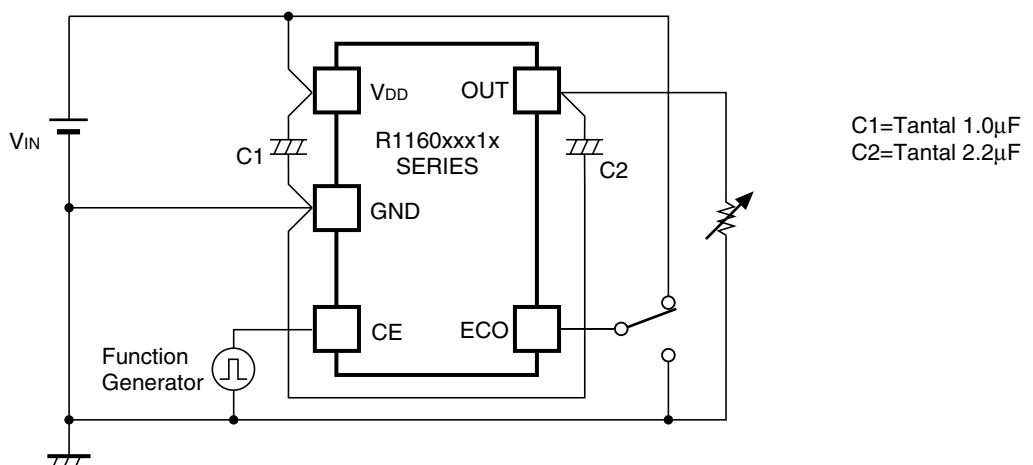


Fig.10 Turn on Speed with CE pin Test Circuit

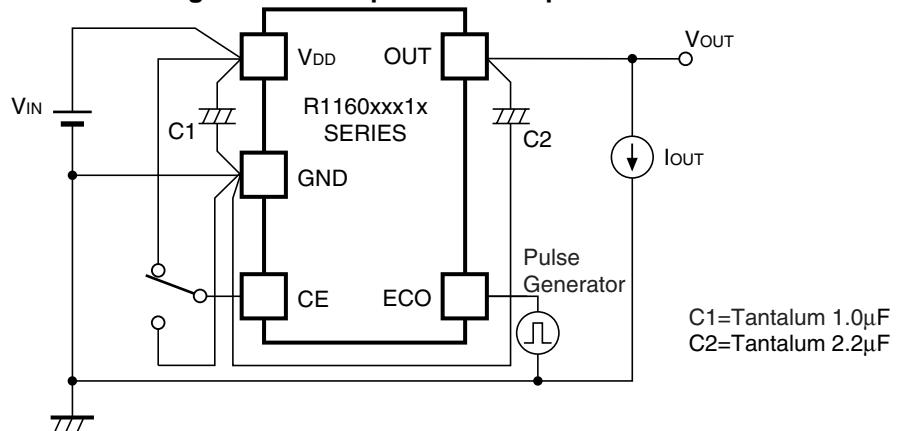


Fig.11 MODE Transient Response Test Circuit

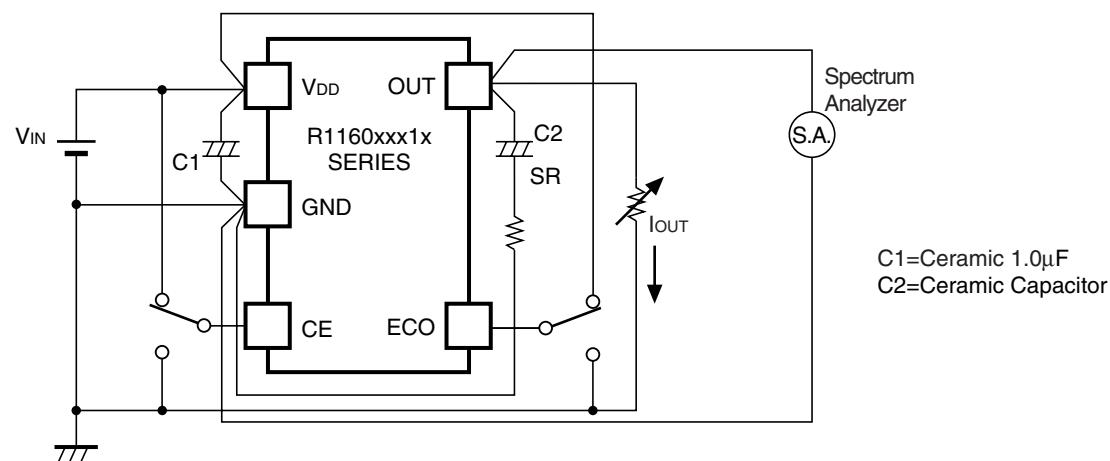
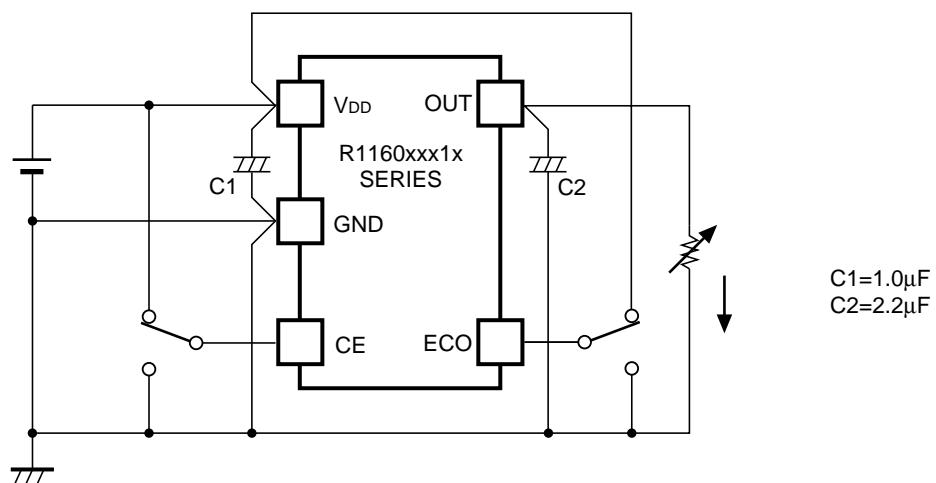


Fig.12 Output Noise Test Circuit (I_{OUT} vs. ESR)

TYPICAL APPLICATION



(External Components)

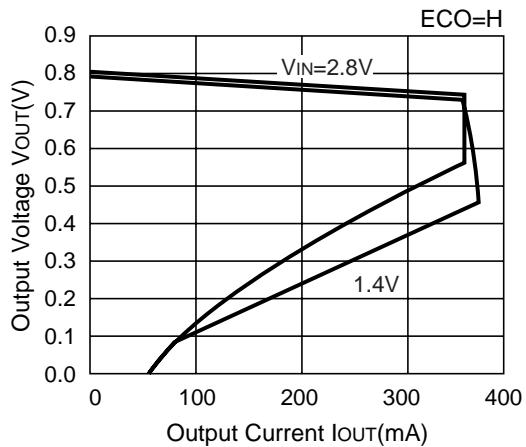
C1: Ceramic Capacitor 1 μ F

C2: Tantalum Capacitor 2.2 μ F

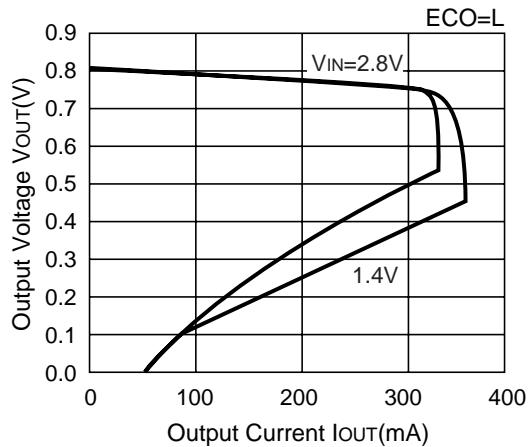
TYPICAL CHARACTERISTICS

1) Output Voltage vs. Output Current

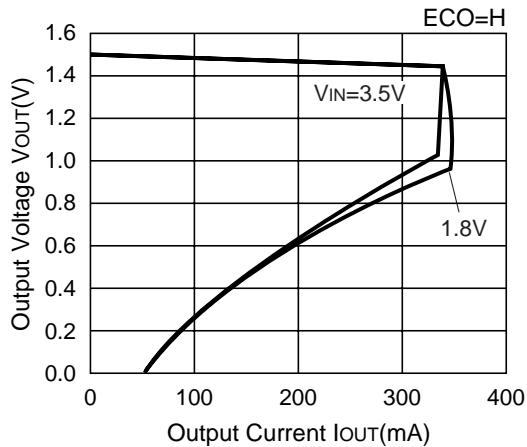
R1160x081x



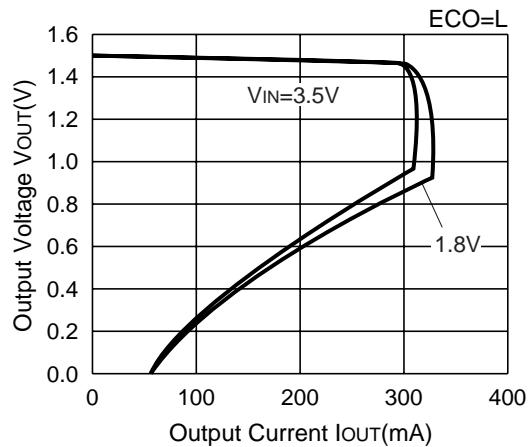
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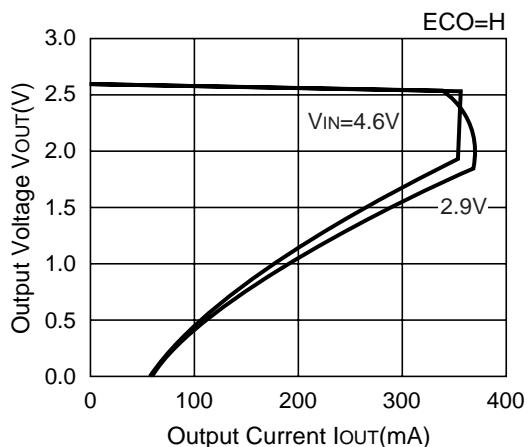
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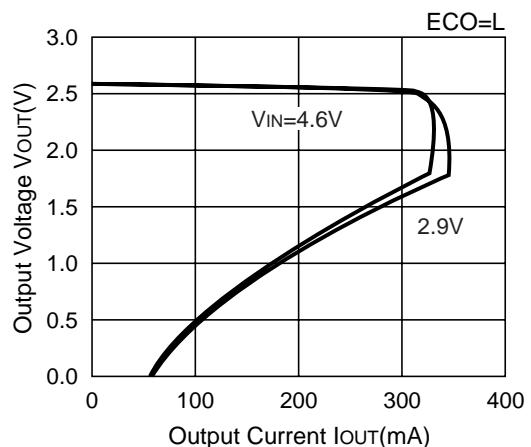
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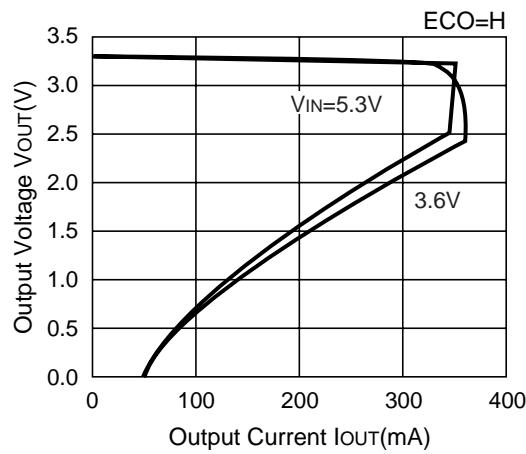
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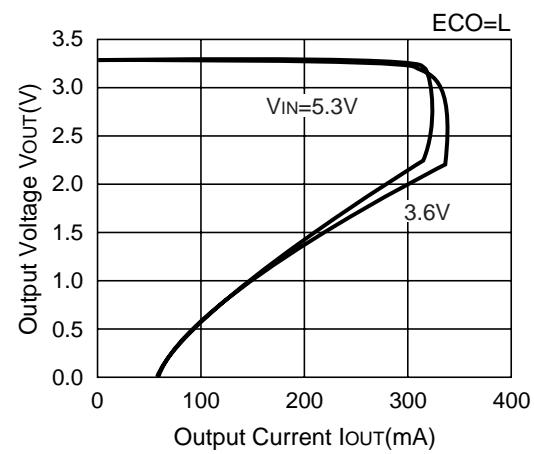
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R1160x331x

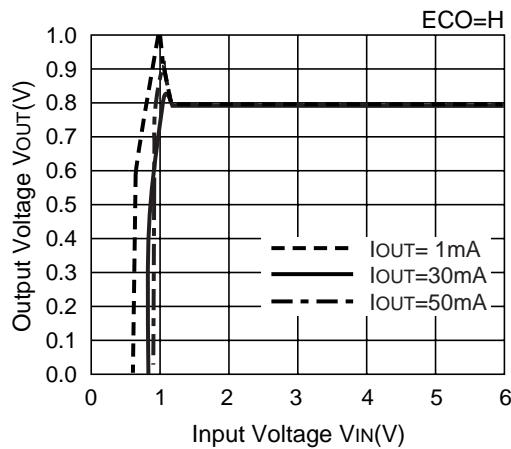


R1160x331x

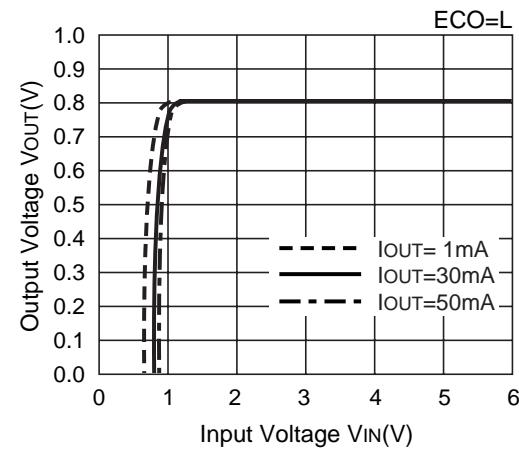


2) Output Voltage vs. Input Voltage

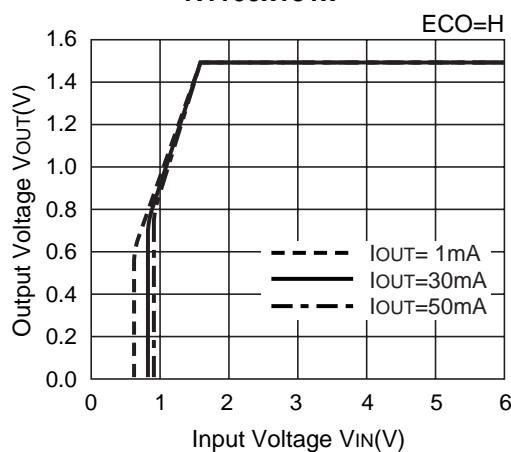
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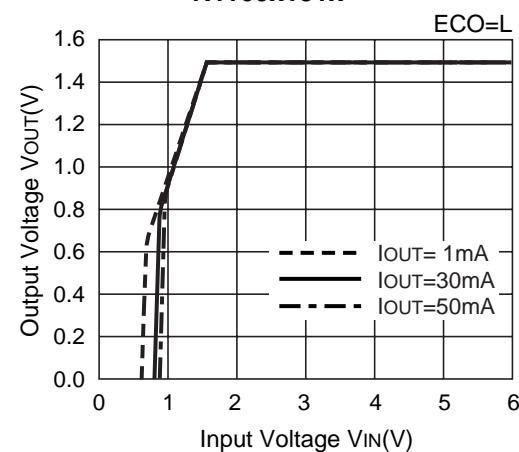
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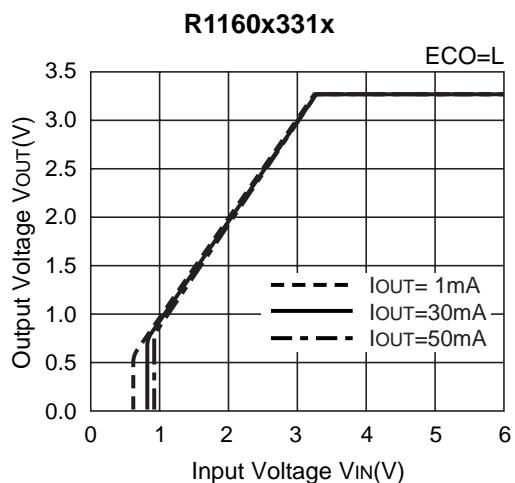
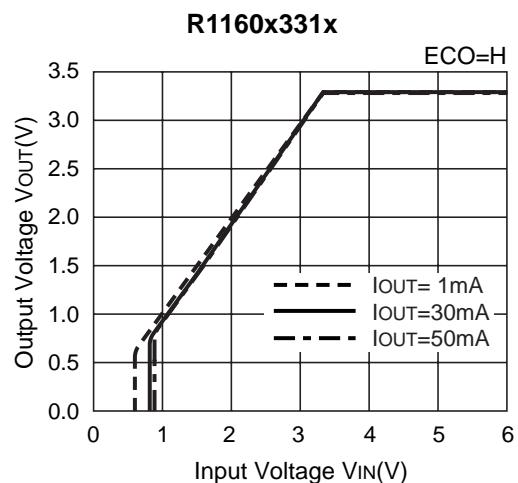
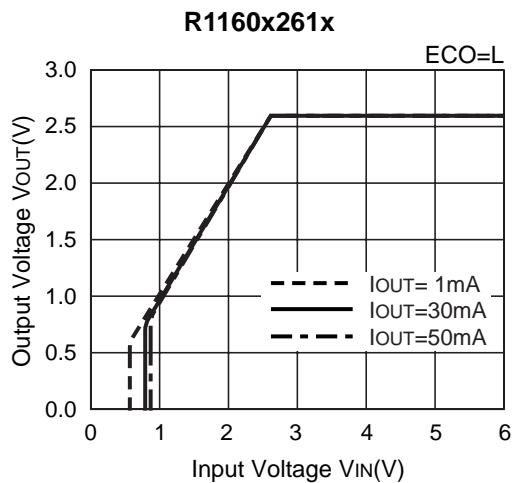
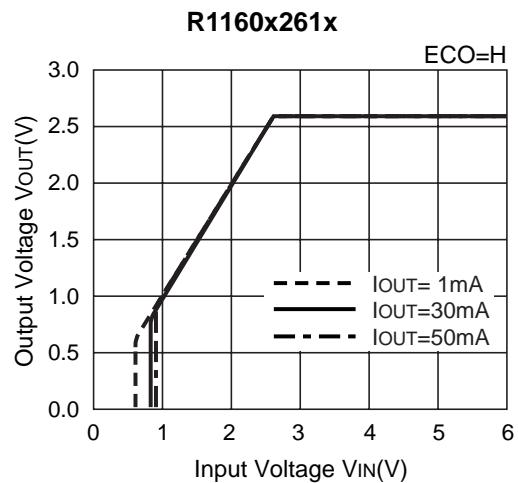
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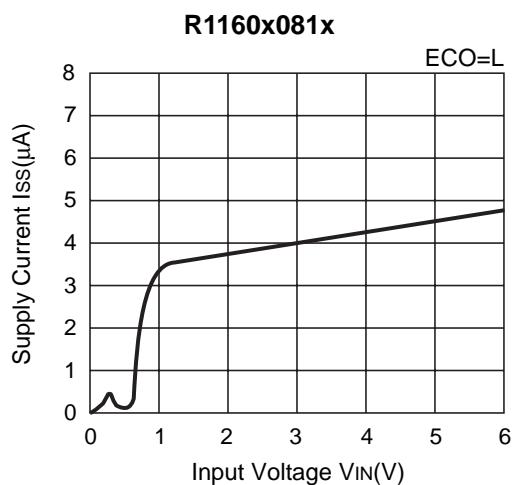
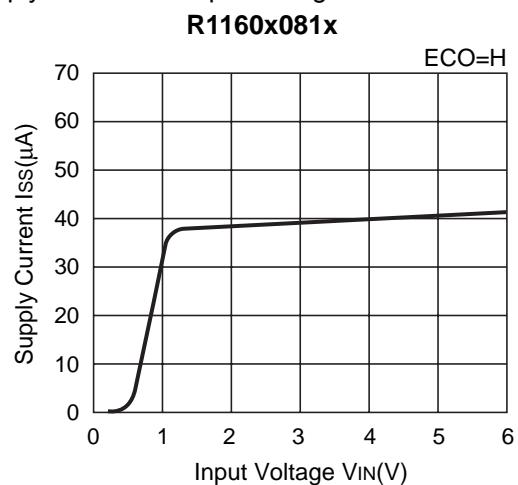
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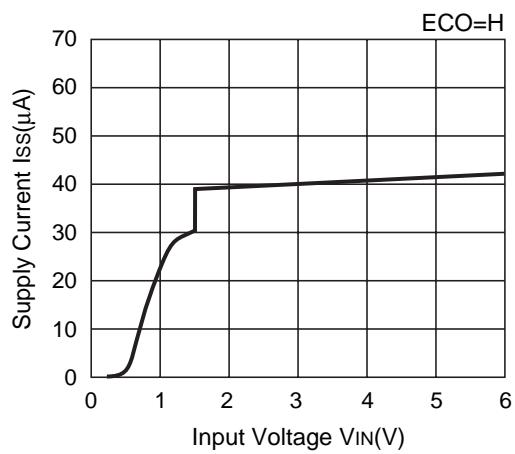
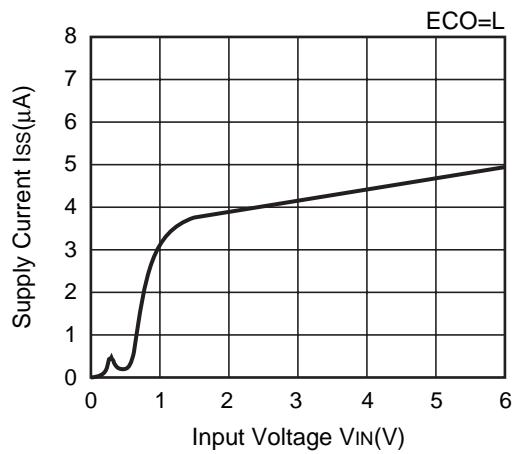
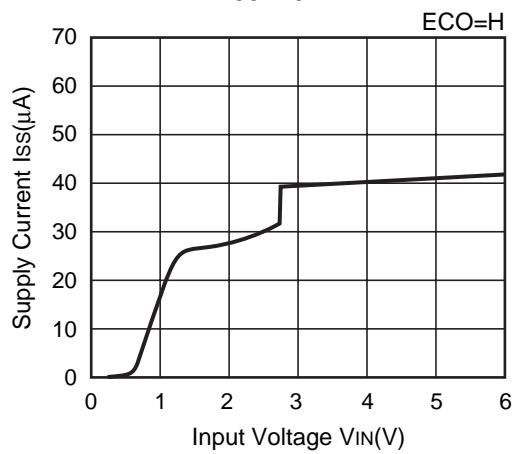
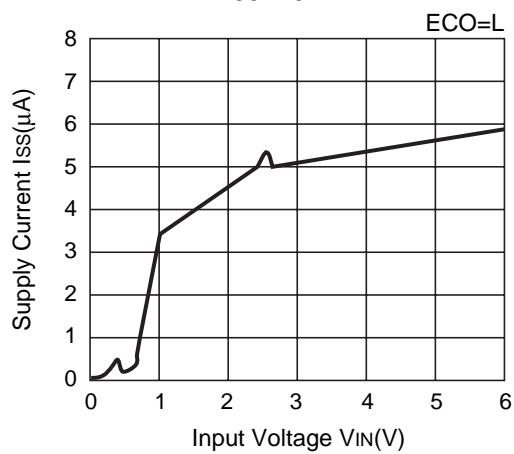
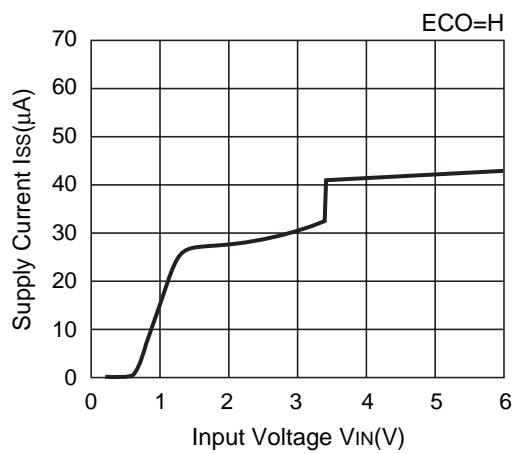
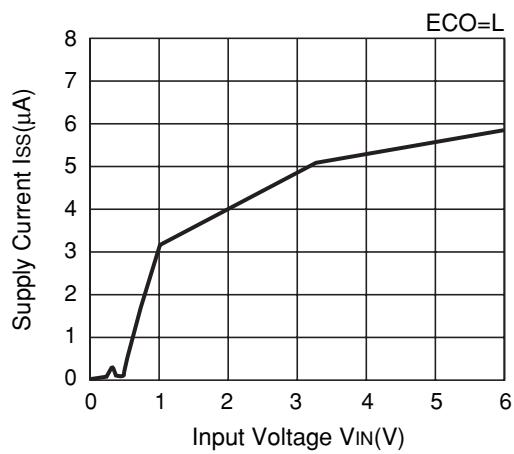


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3) Supply Current vs. Input Voltage

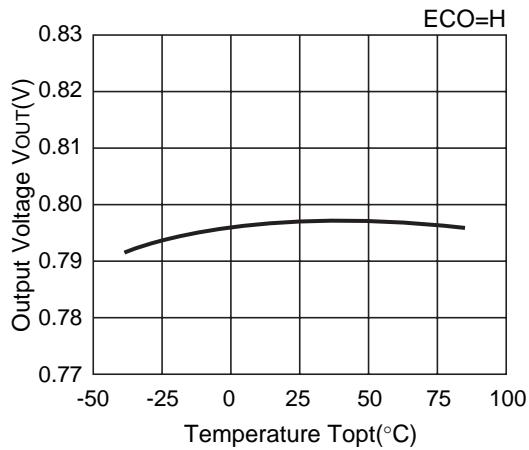


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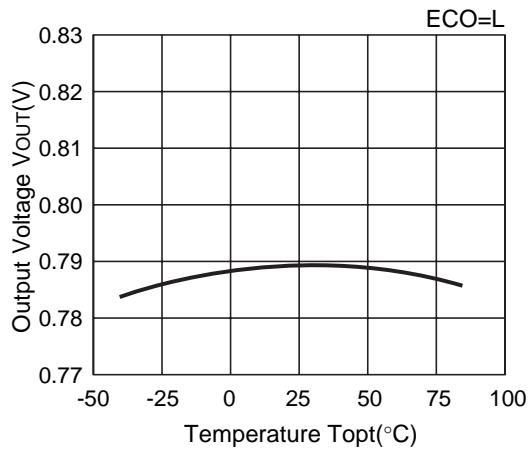
R1160x

4) Output Voltage vs. Temperature

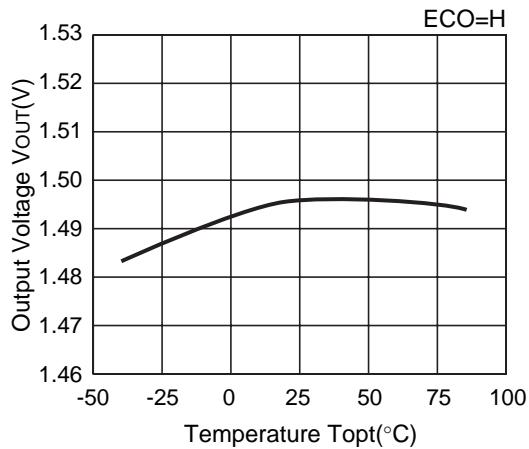
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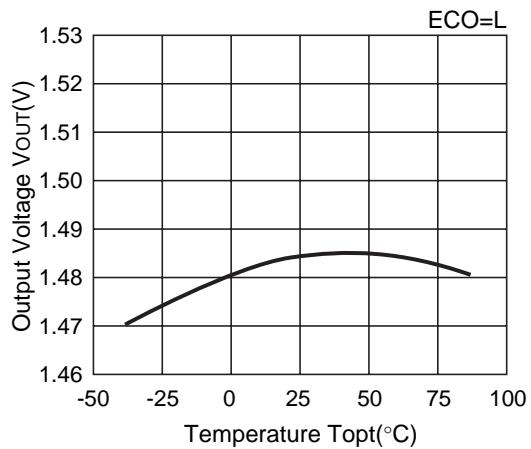
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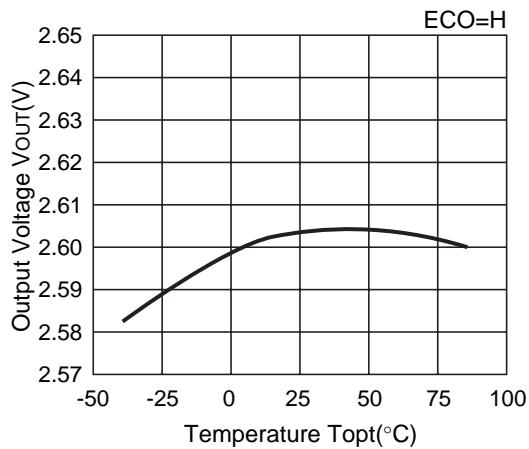
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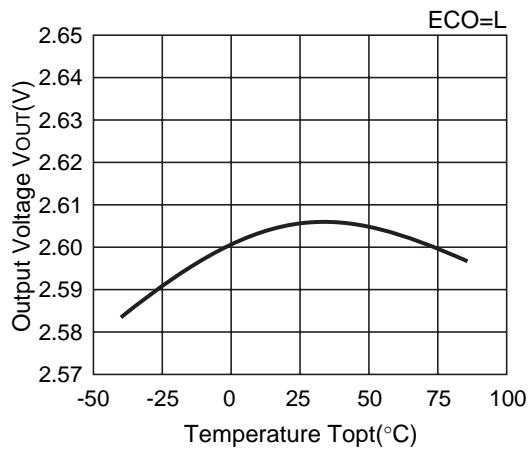
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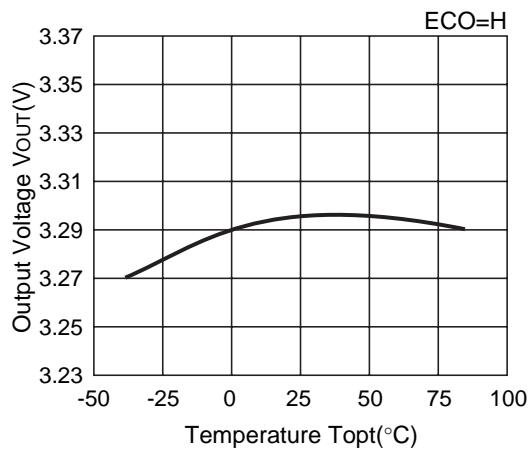
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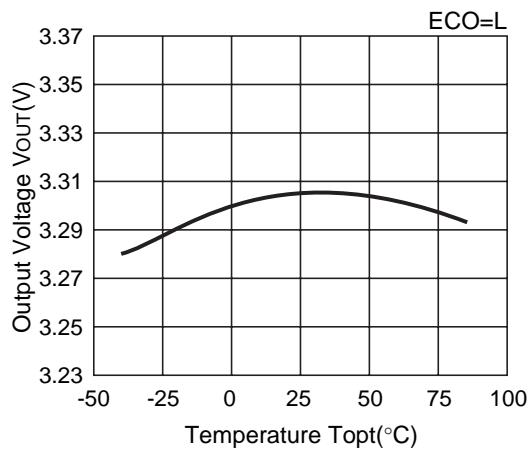
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R1160x331x

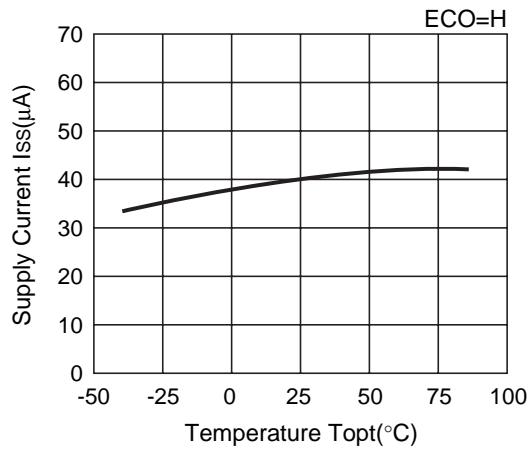


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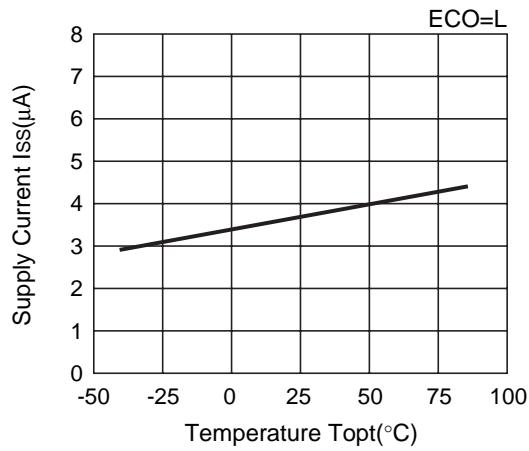


5) Supply Current vs. Input Voltage

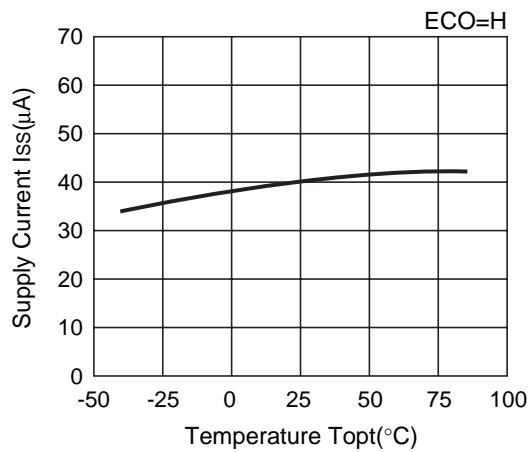
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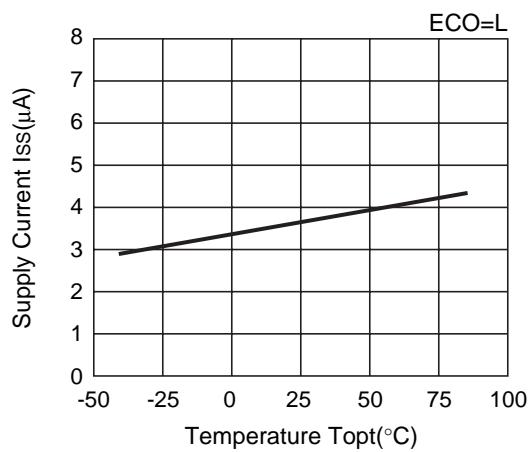
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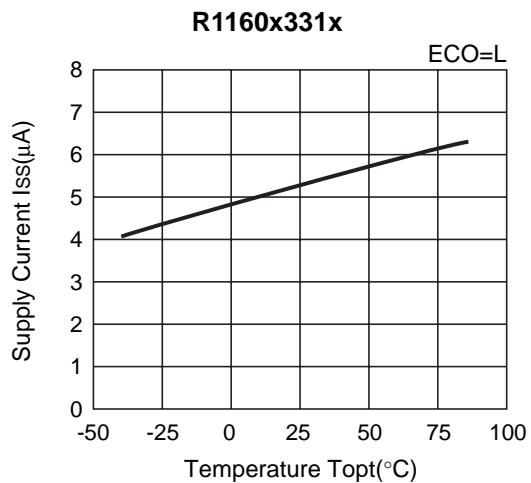
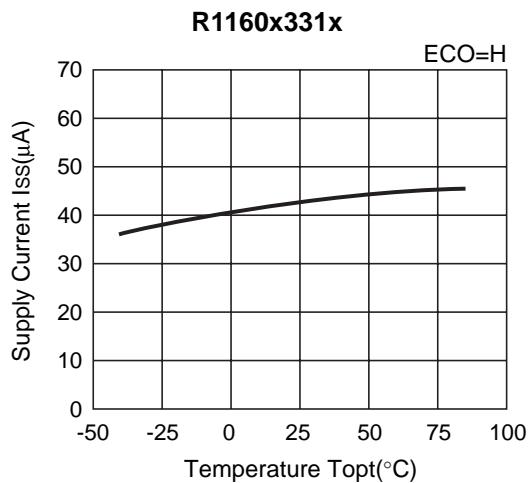
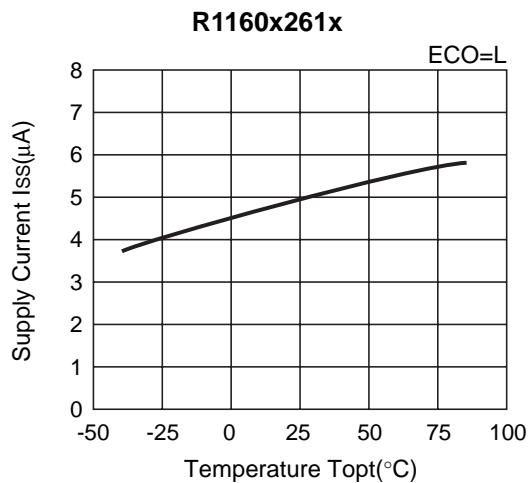
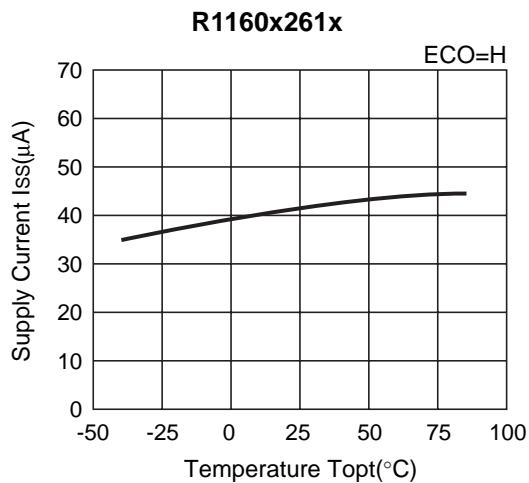
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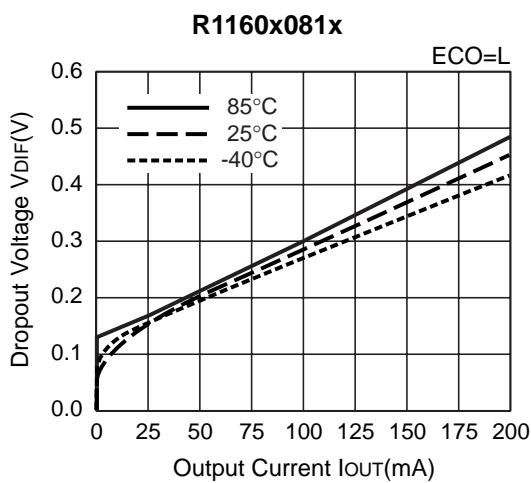
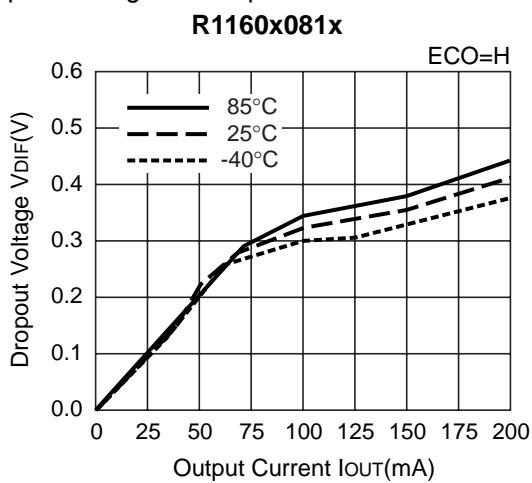
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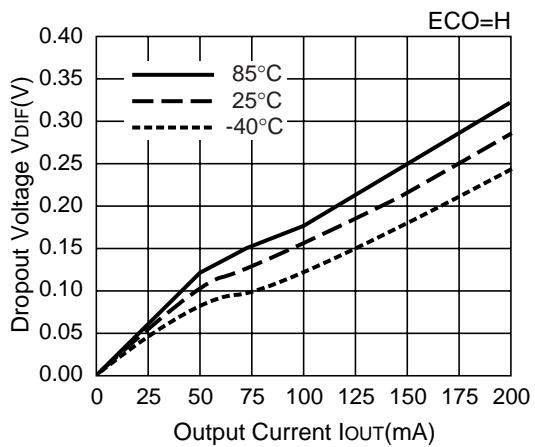
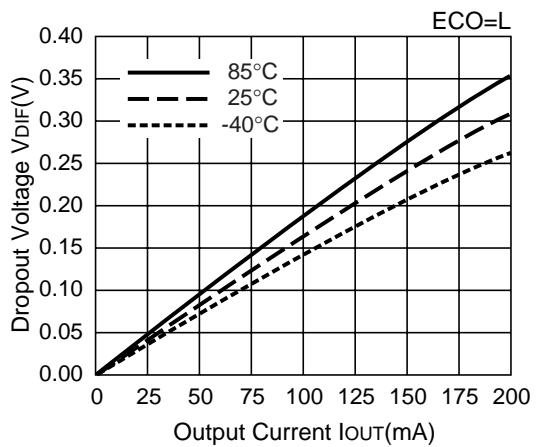
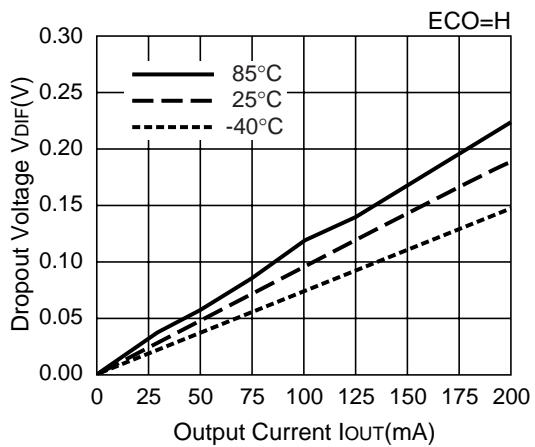
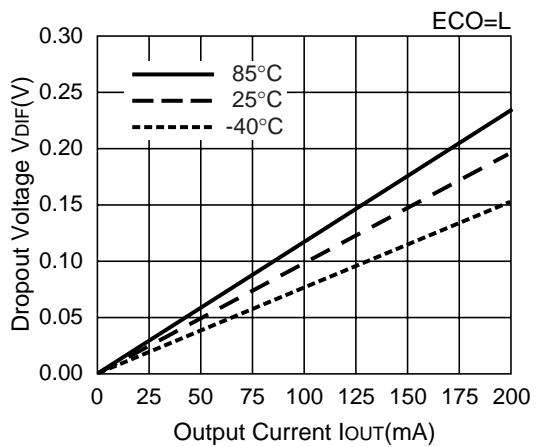
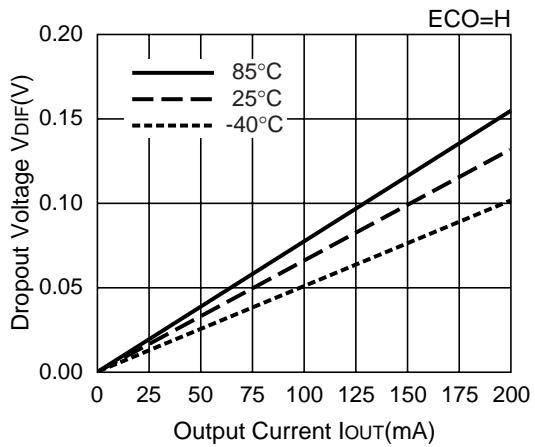
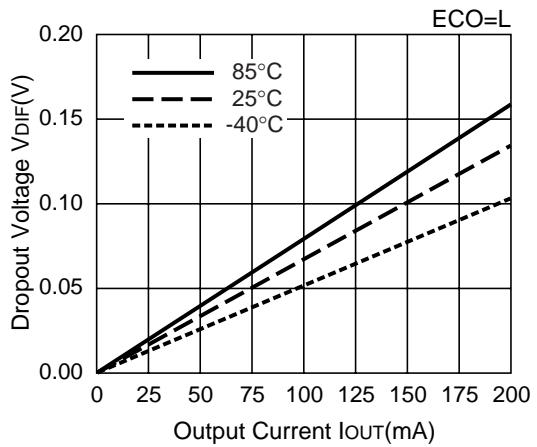


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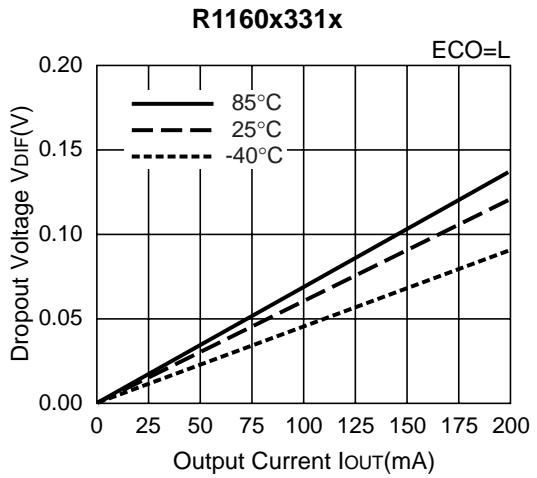
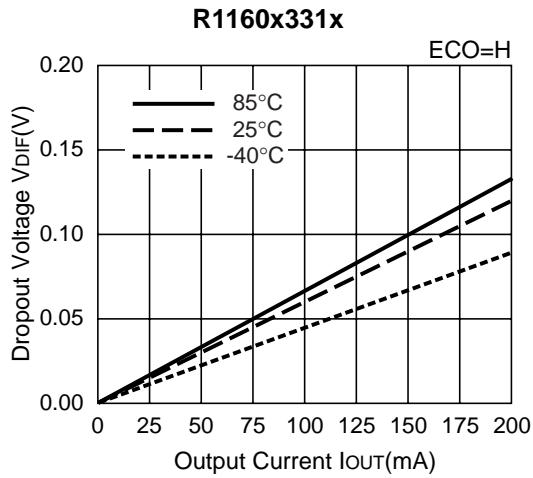


6) Dropout Voltage vs. Output Current

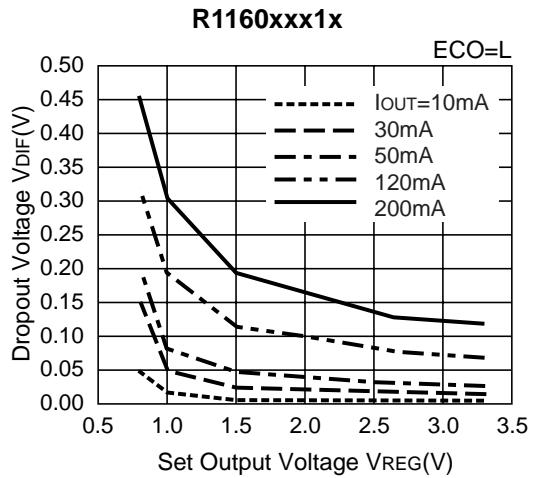
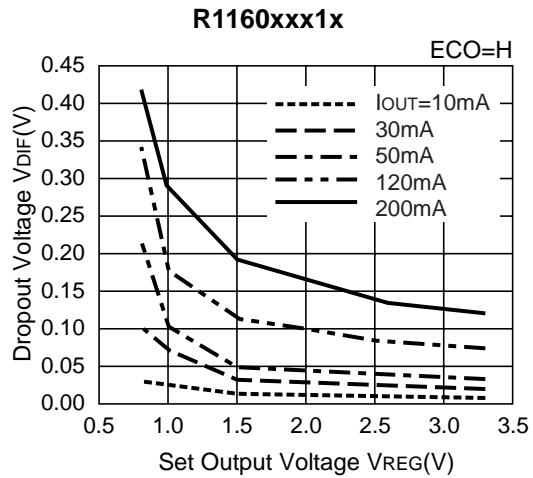


R1160x101x**R1160x101x****R1160x151x****R1160x151x****R1160x261x****R1160x261x**

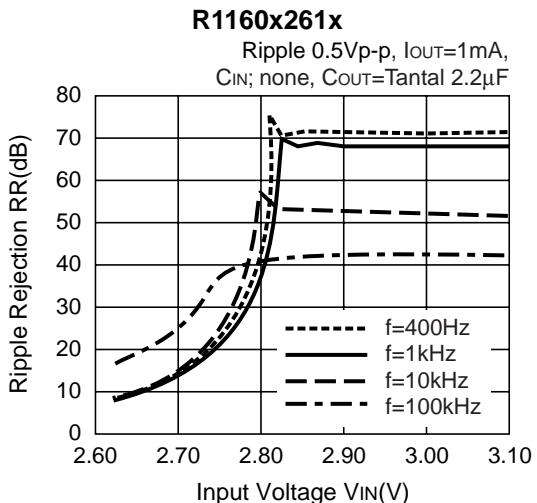
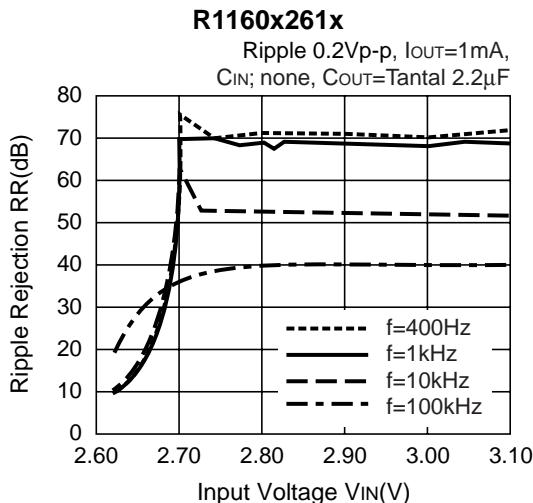
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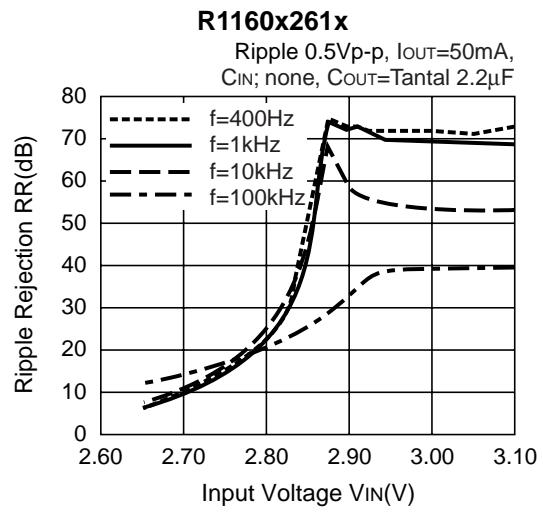
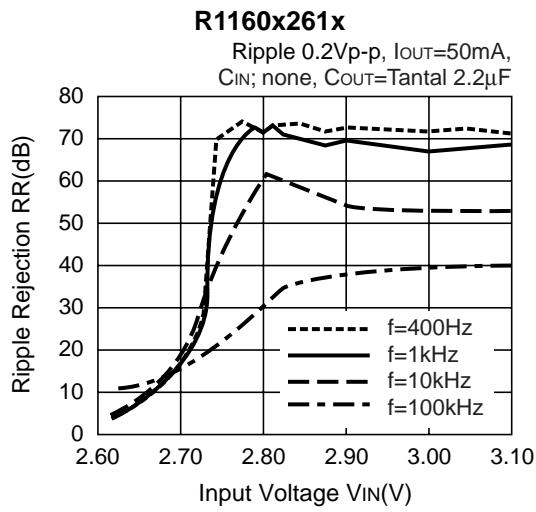
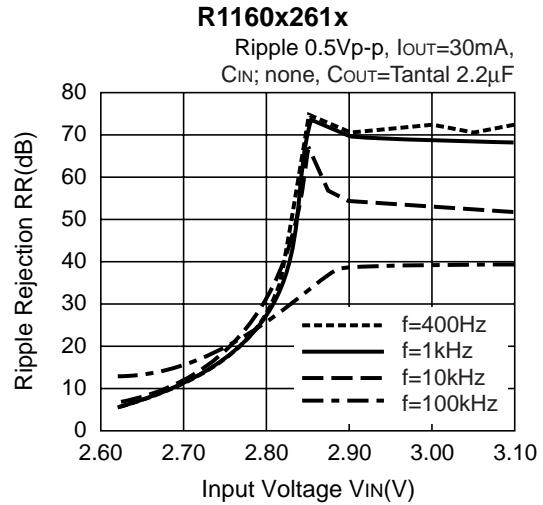
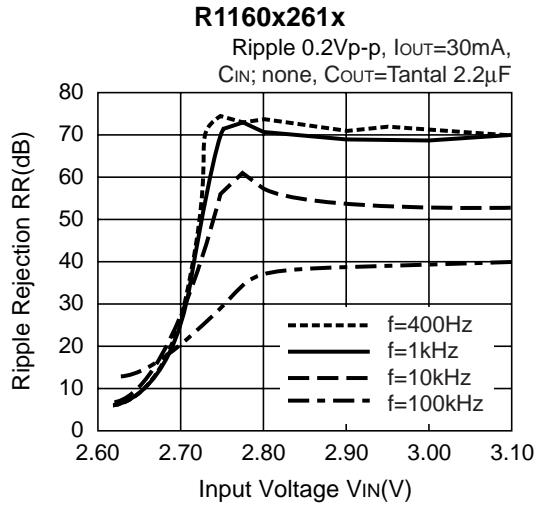


7) Dropout Voltage vs. Set Output Voltage ($T_{opt}=25^{\circ}\text{C}$)

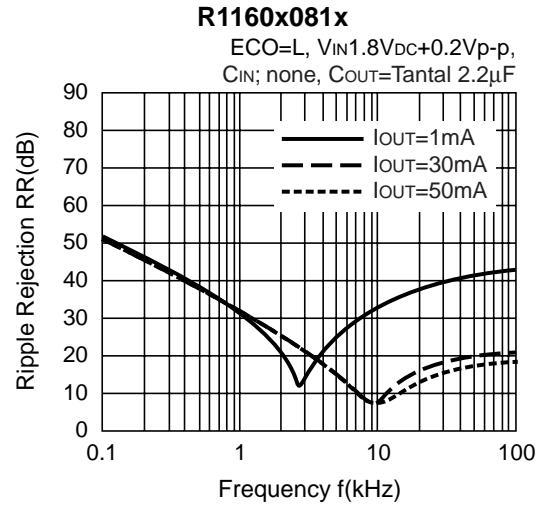
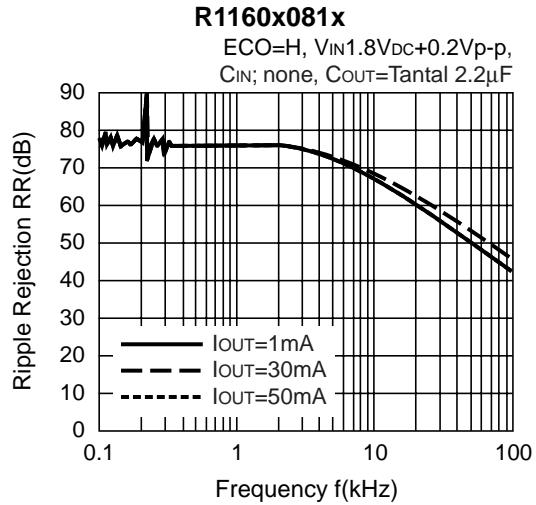


8) Ripple Rejection vs. Input Bias ($T_{opt}=25^{\circ}\text{C}$)





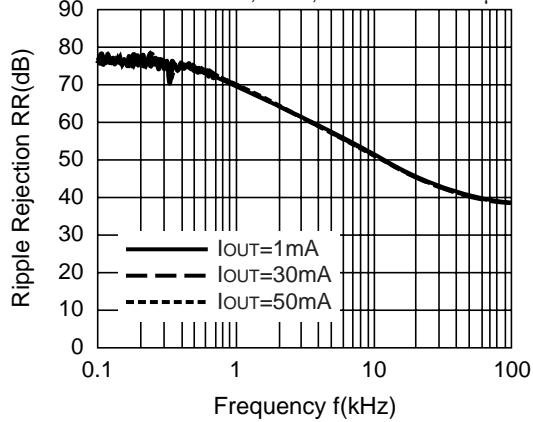
9) Ripple Rejection vs. Frequency



R1160x

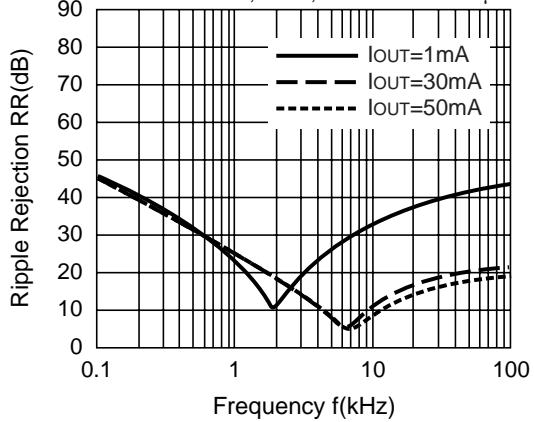
R1160x151x

ECO=H, $V_{IN}2.5V_{DC}+0.2V_{P-P}$,
C_{IN}; none, C_{OUT}=Tantal 2.2μF



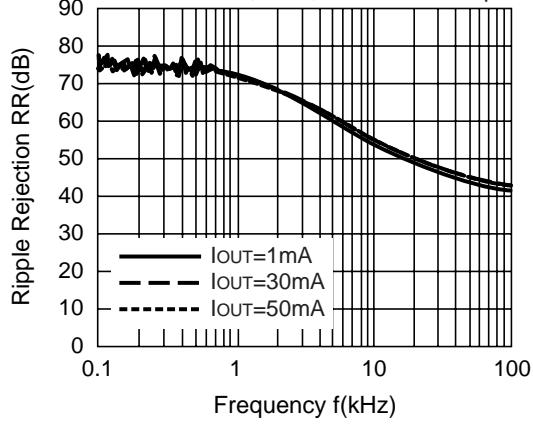
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ECO=L, $V_{IN}2.5V_{DC}+0.2V_{P-P}$,
C_{IN}; none, C_{OUT}=Tantal 2.2μF



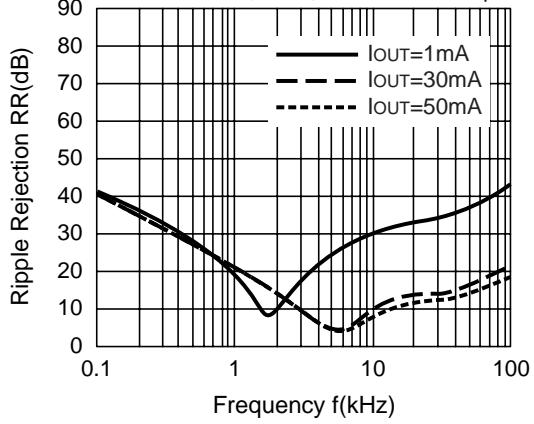
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ECO=H, $V_{IN}3.6V_{DC}+0.2V_{P-P}$,
C_{IN}; none, C_{OUT}=Tantal 1.0μF



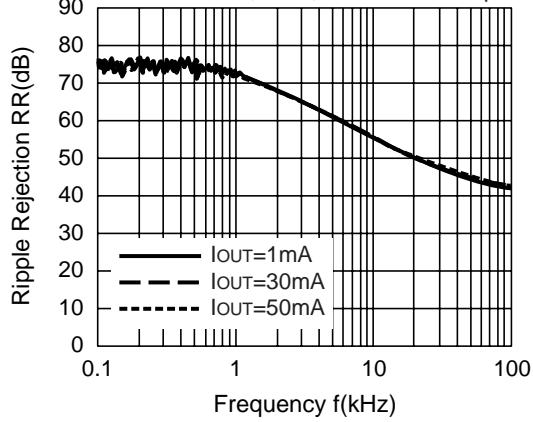
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ECO=L, $V_{IN}3.6V_{DC}+0.2V_{P-P}$,
C_{IN}; none, C_{OUT}=Tantal 1.0μF



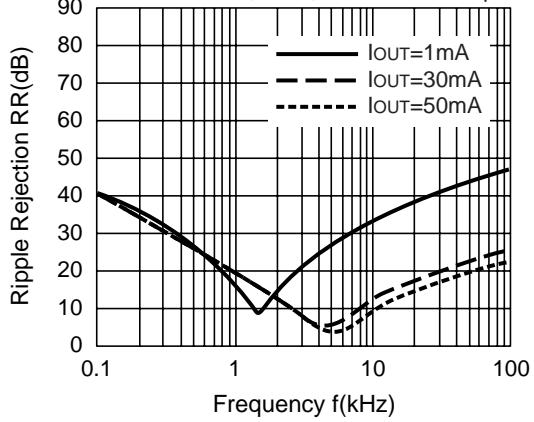
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ECO=H, $V_{IN}3.6V_{DC}+0.2V_{P-P}$,
C_{IN}; none, C_{OUT}=Tantal 2.2μF



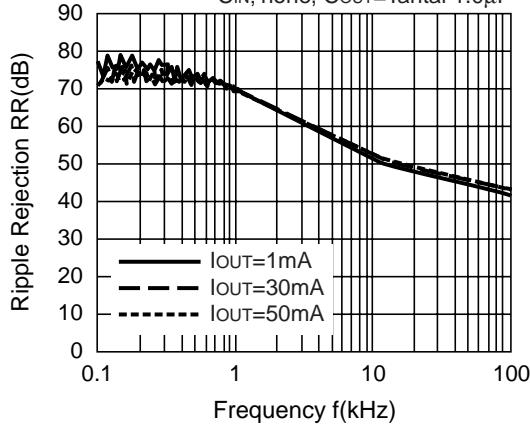
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ECO=L, $V_{IN}3.6V_{DC}+0.2V_{P-P}$,
C_{IN}; none, C_{OUT}=Tantal 2.2μF



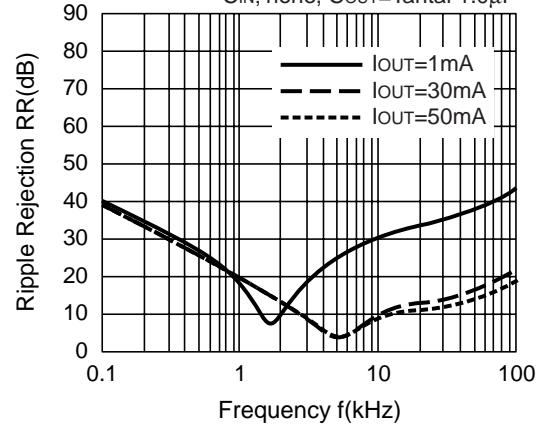
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ECO=H, V_{IN} 4.3Vdc+0.2Vp-p,
 C_{IN} : none, C_{OUT} =Tantal 1.0 μ F



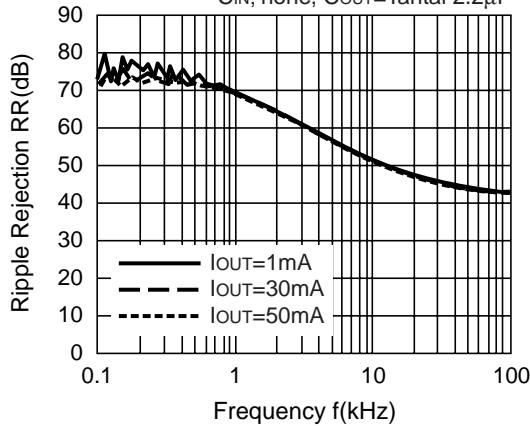
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ECO=L, V_{IN} 4.3Vdc+0.2Vp-p,
 C_{IN} : none, C_{OUT} =Tantal 1.0 μ F



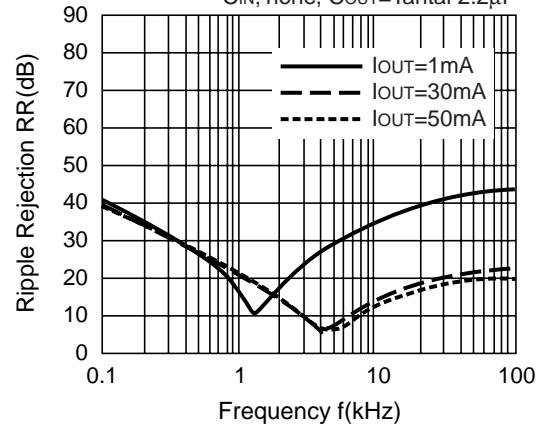
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ECO=H, V_{IN} 4.3Vdc+0.2Vp-p,
 C_{IN} : none, C_{OUT} =Tantal 2.2 μ F



R1160x331x

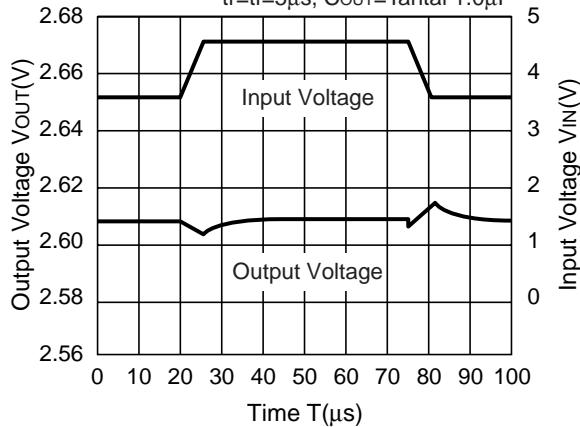
ECO=L, V_{IN} 4.3Vdc+0.2Vp-p,
 C_{IN} : none, C_{OUT} =Tantal 2.2 μ F



10) Input Transient Response

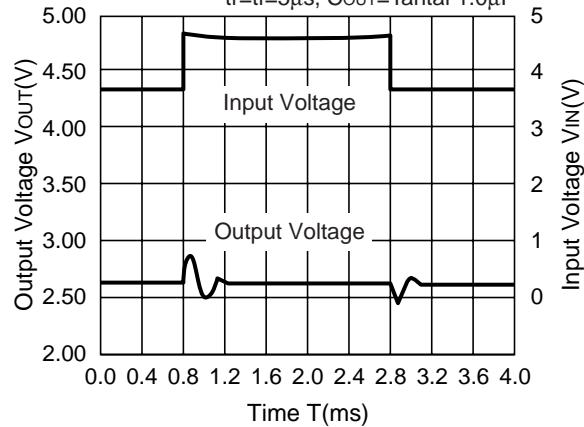
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ECO=H, I_{OUT} =30mA,
 $t_r=t_f=5\mu$ s, C_{OUT} =Tantal 1.0 μ F



R1160x261x

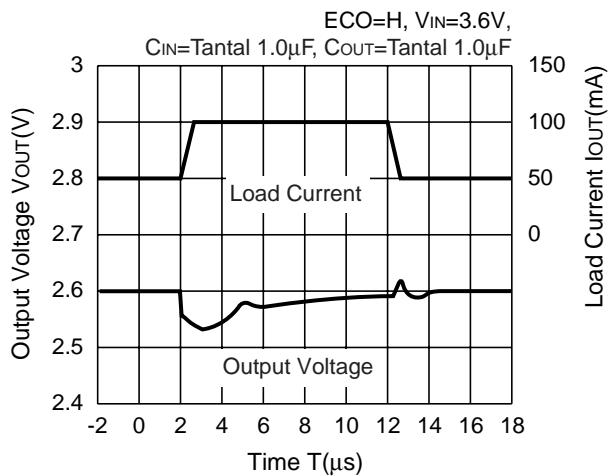
ECO=L, I_{OUT} =10mA,
 $t_r=t_f=5\mu$ s, C_{OUT} =Tantal 1.0 μ F



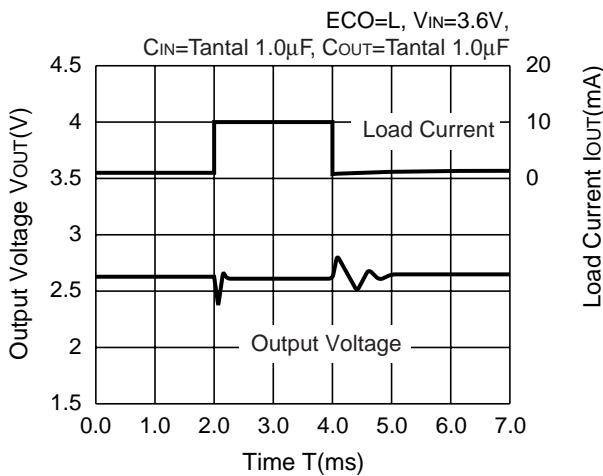
R1160x

11) Load Transient Response

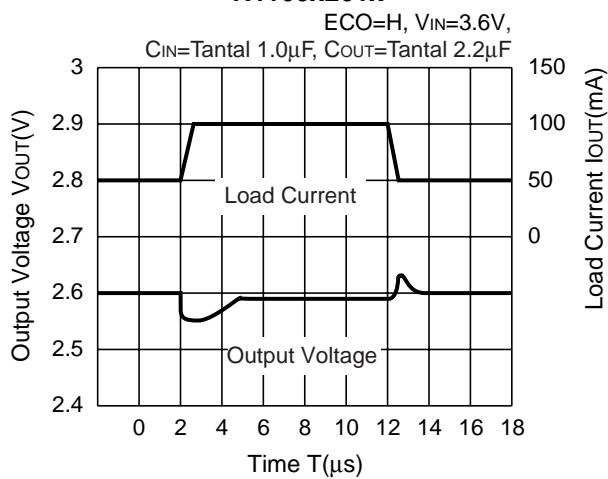
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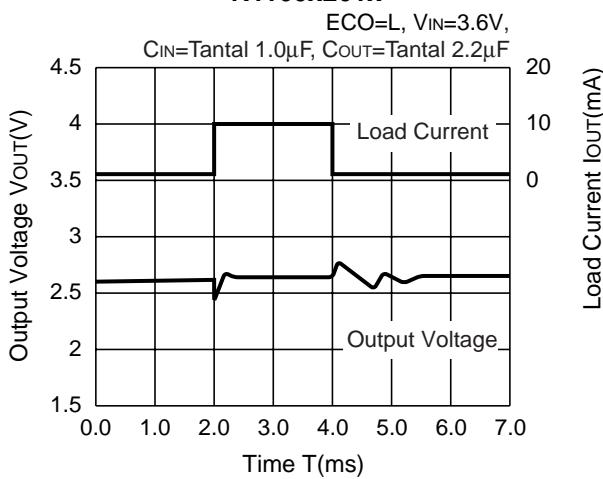
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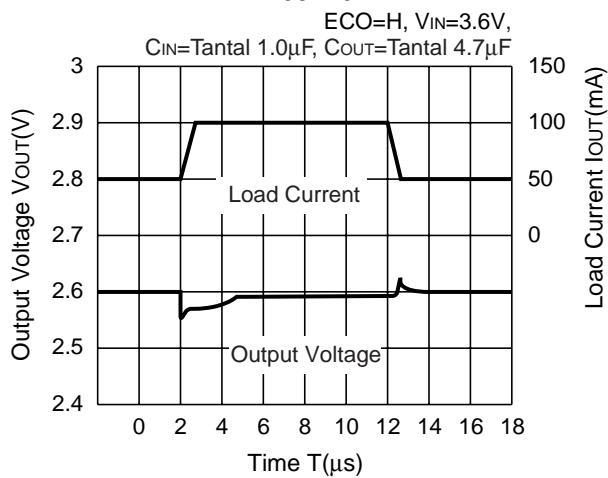
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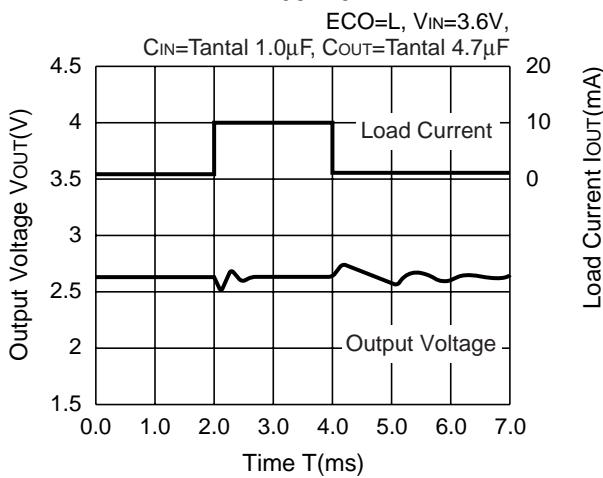
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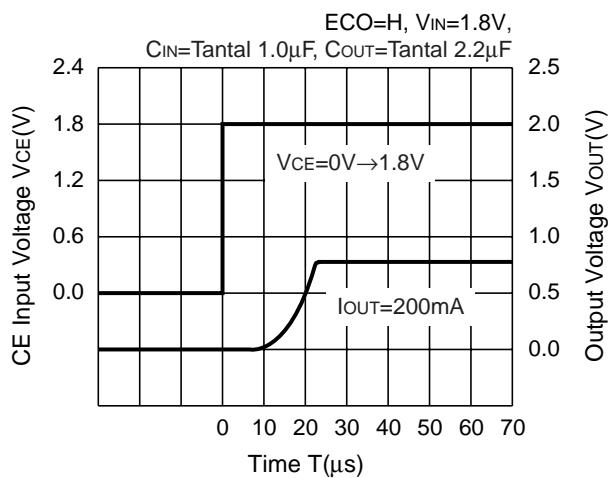


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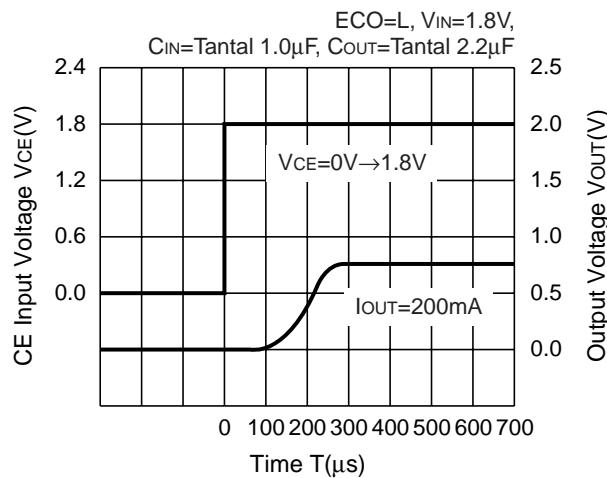


12) Turn on speed with CE pin

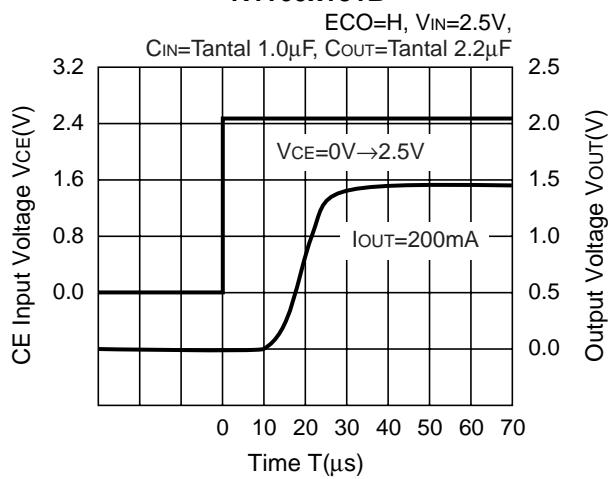
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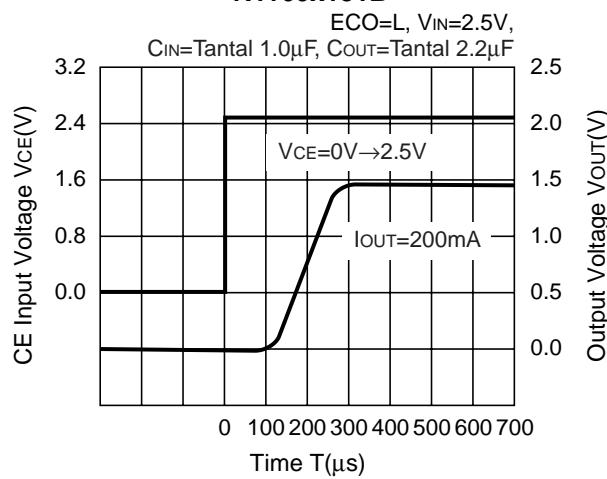
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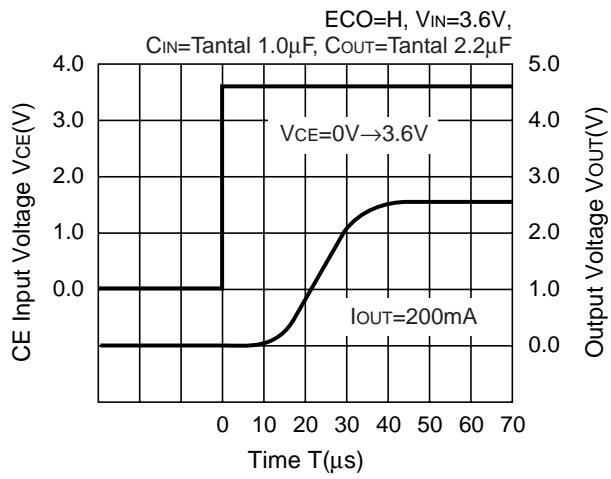
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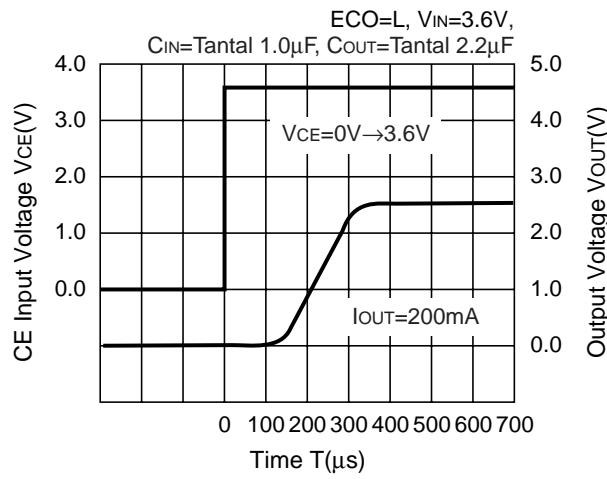
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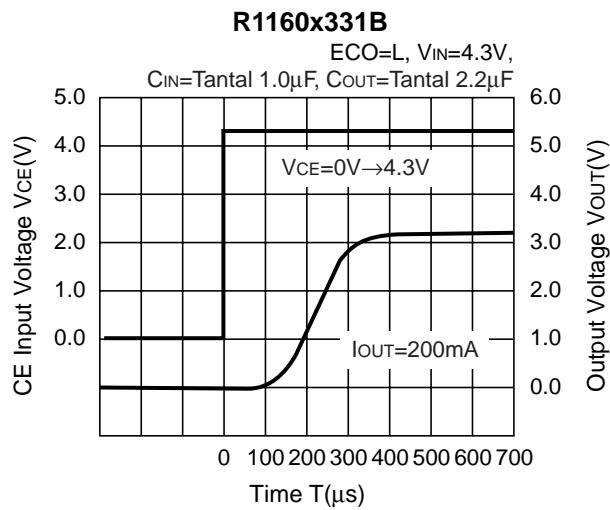
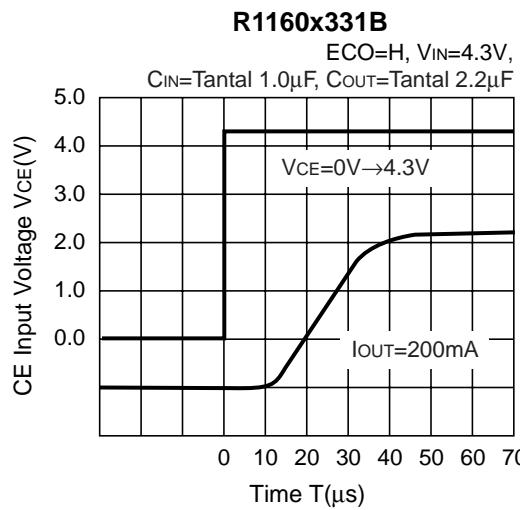
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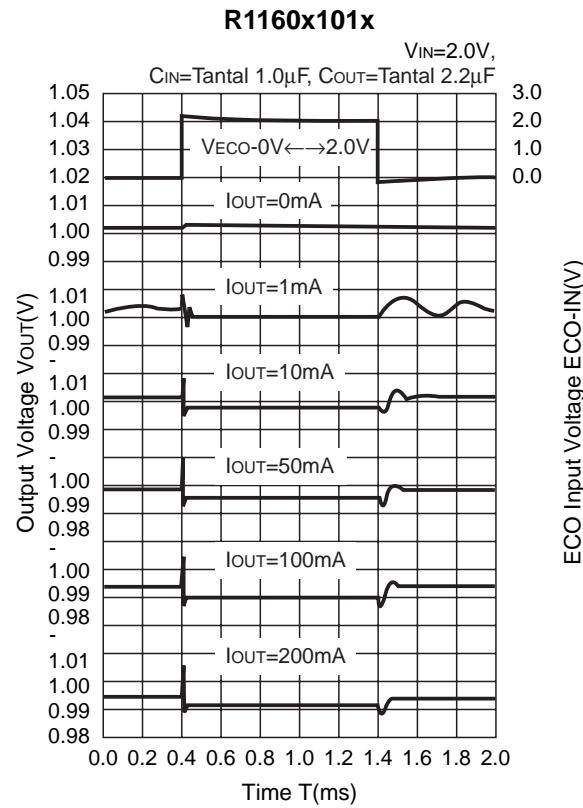
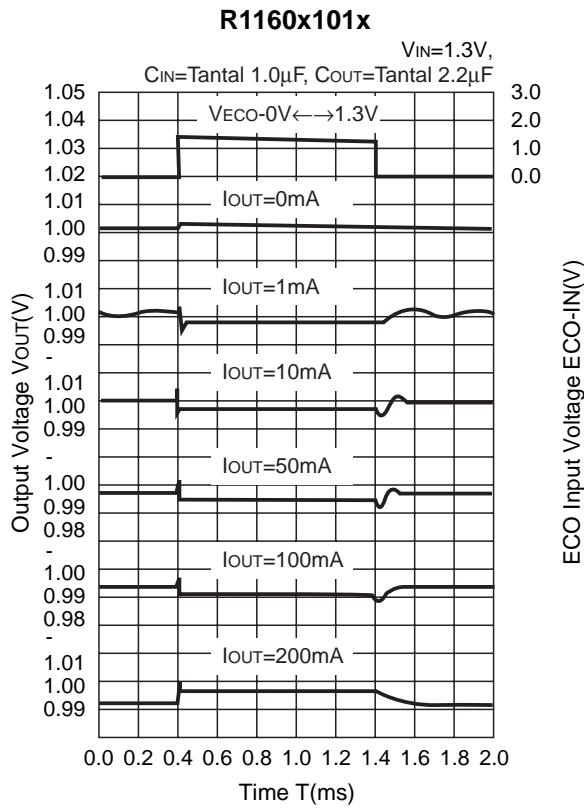
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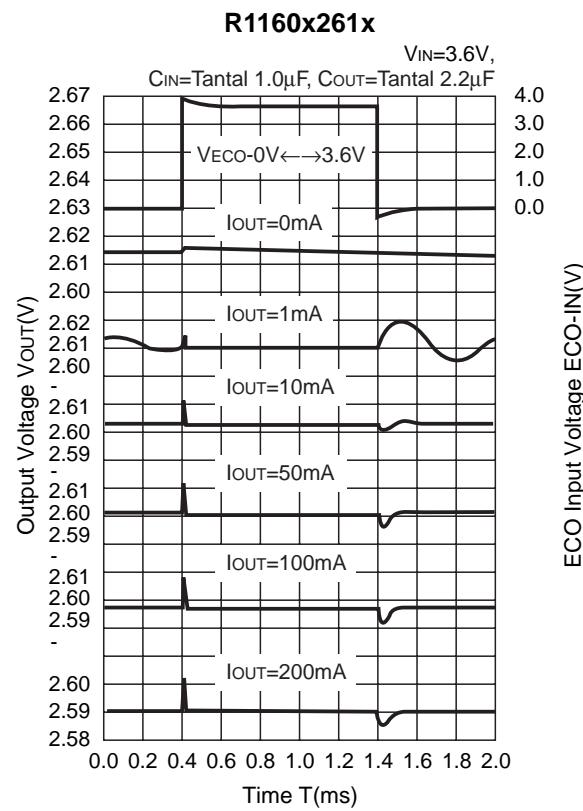
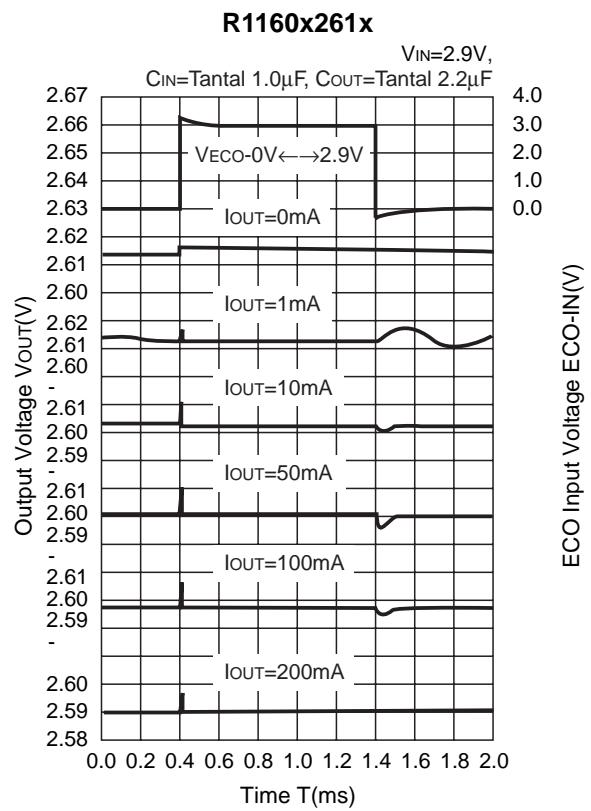


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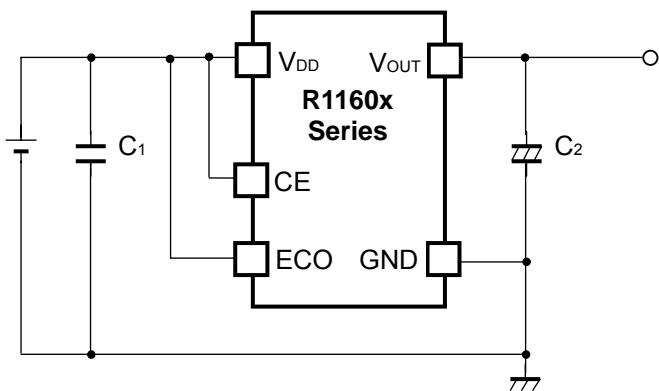


13) Output Voltage at Mode alternative point





TECHNICAL NOTES



(External Components)

C1: Ceramic Capacitor 1 μ F

C2: Tantalum Capacitor 2.2 μ F

When using these ICs, consider the following points:

1. PCB Layout

Make V_{DD} and GND lines sufficient. If their impedance is high, noise pickup or unstable operation may result. Connect a capacitor C1 with a capacitance value as much as 1.0 μ F or more between V_{DD} and GND pin, and as close as possible to the pins.

Set external components, especially the output capacitor C2, as close as possible to the ICs, and make wiring as short as possible.

2. Phase Compensation

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, use a capacitor C2 with 2.2 μ F or more and good ESR (Equivalent Series Resistance).

(Note: If additional ceramic capacitors are connected with parallel to the output pin with an output capacitor for phase compensation, the operation might be unstable. Because of this, test these ICs with same external components as ones to be used on the PCB.)

If you use a tantalum type capacitor and ESR value of the capacitor is large, output might be unstable. Evaluate your circuit with considering frequency characteristics.

If you use a ceramic type output capacitor, please connect about 1 Ω resistor in series for the stability of output voltage.

Depending on the capacitor size, manufacturer, and part number, the bias characteristics and temperature characteristics are different. Evaluate the circuit with actual using capacitors.

ESR vs. Output Current

When using these ICs, consider the following points:

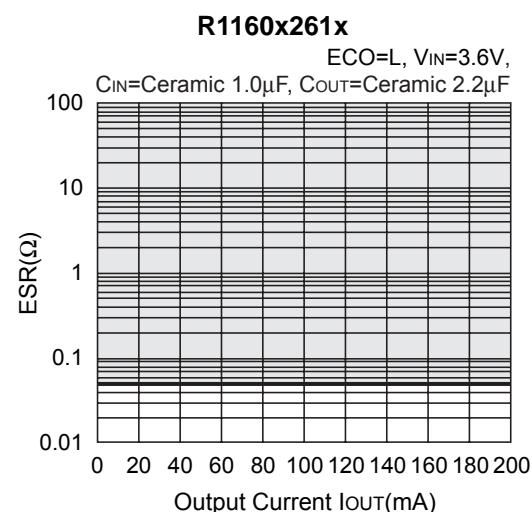
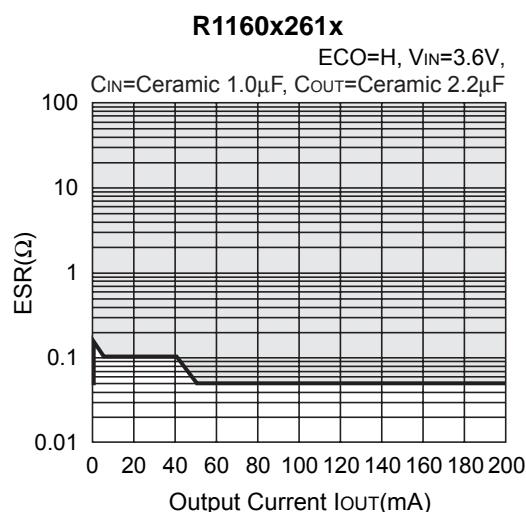
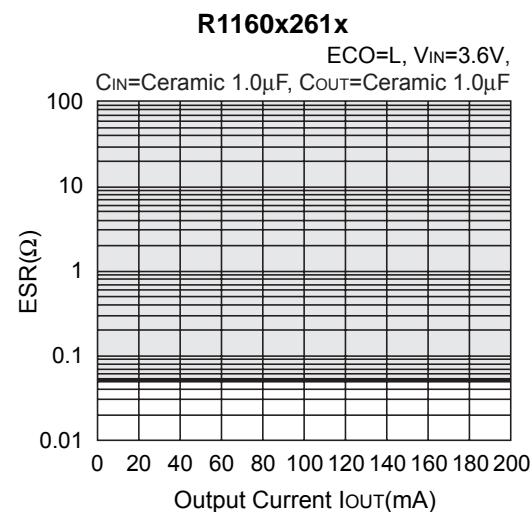
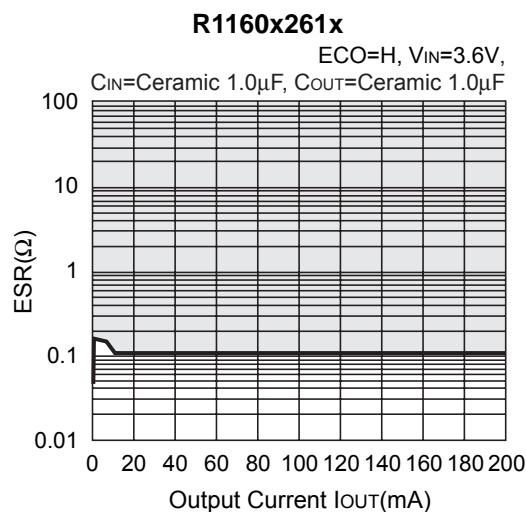
The relations between I_{OUT} (Output Current) and ESR of an output capacitor are shown below.

The conditions when the white noise level is under $40\mu V$ (Avg.) are marked as the hatched area in the graph.

Measurement conditions

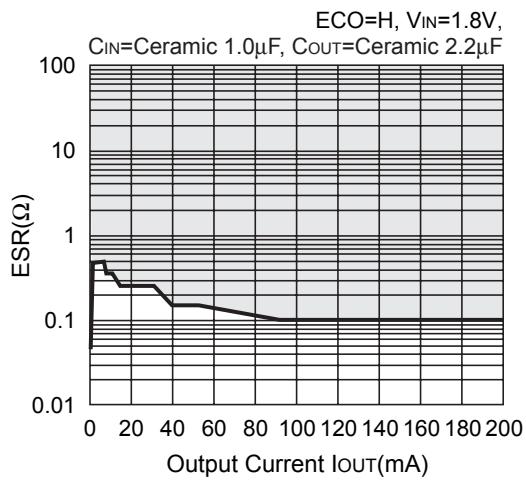
Frequency Band : 10Hz to 2MHz

Temperature : 25°C

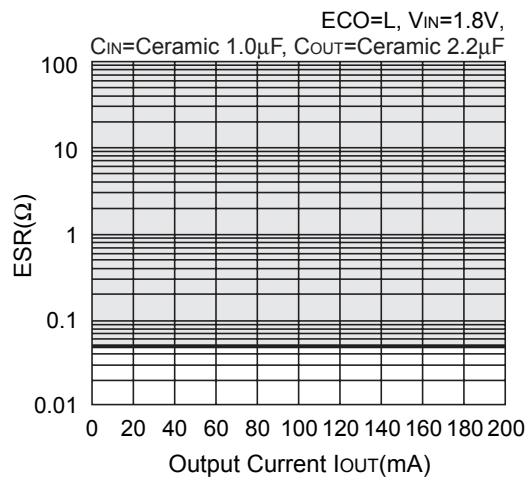


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5. The products listed in this document are intended and designed for use as general electronic components in standard applications (office equipment, telecommunication equipment, measuring instruments, consumer electronic products, amusement equipment etc.). Those customers intending to use a product in an application requiring extreme quality and reliability, for example, in a highly specific application where the failure or misoperation of the product could result in human injury or death (aircraft, spacevehicle, nuclear reactor control system, traffic control system, automotive and transportation equipment, combustion equipment, safety devices, life support system etc.) should first contact us.
6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, firecontainment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
7. Anti-radiation design is not implemented in the products described in this document.
8. Please contact Ricoh sales representatives should you have any questions or comments concerning the products or the technical information.

RICOH COMPANY, LTD. Electronic Devices Company



■Ricoh presented with the Japan Management Quality Award for 1999.
Ricoh continually strives to promote customer satisfaction, and shares the achievements of its management quality improvement program with people and society.



■Ricoh awarded ISO 14001 certification.
The Ricoh Group was awarded ISO 14001 certification, which is an international standard for environmental management systems, at both its domestic and overseas production facilities. Our current aim is to obtain ISO 14001 certification for all of our business offices.

<http://www.ricoh.com/LSI/>

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Ricoh completed the organization of the Lead-free production for all of our products. After Apr. 1, 2006, we will ship out the lead free products only. Thus, all products that will be shipped from now on comply with RoHS Directive.